

SCHOOL OF ELECTRONICS ENGINEERING

M. Tech Nanotechnology

(M.Tech MNT)

Curriculum

(2018-2019 admitted students)

VISION STATEMENT OF VELLORE INSTITUTE OF TECHNOLOGY

Transforming life through excellence in education and research.

MISSION STATEMENT OF VELLORE INSTITUTE OF TECHNOLOGY

World class Education: Excellence in education, grounded in ethics and critical thinking, for improvement of life.

Cutting edge Research: An innovation ecosystem to extend knowledge and solve critical problems.

Impactful People: Happy, accountable, caring and effective workforce and students.

Rewarding Co-creations: Active collaboration with national & international industries & universities for productivity and economic development.

Service to Society: Service to the region and world through knowledge and compassion.

VISION STATEMENT OF THE SCHOOL OF ELECTRONICS ENGINEERING

To be a leader by imparting in-depth knowledge in Electronics Engineering, nurturing engineers, technologists and researchers of highest competence, who would engage in sustainable development to cater the global needs of industry and society.

MISSION STATEMENT OF THE SCHOOL OF ELECTRONICS ENGINEERING

- Create and maintain an environment to excel in teaching, learning and applied research in the fields of electronics, communication engineering and allied disciplines which pioneer for sustainable growth.
- Equip our students with necessary knowledge and skills which enable them to be lifelong learners to solve practical problems and to improve the quality of human life.

M. Tech. Nanotechnology

PROGRAMME EDUCATIONAL OBJECTIVES (PEOs)

1. Graduates will be engineering practitioners and leaders, who would help solve industry's technological problems.

2. Graduates will be engineering professionals, innovators or entrepreneurs engaged in technology development, technology deployment, or engineering system implementation in industry.

3. Graduates will function in their profession with social awareness and responsibility.

4. Graduates will interact with their peers in other disciplines in industry and society and contribute to the economic growth of the country.

5. Graduates will be successful in pursuing higher studies in engineering or management.

6. Graduates will pursue career paths in teaching or research.

M. Tech Nanotechnology

PROGRAMME OUTCOMES (POs)

PO_01: Having an ability to apply mathematics and science in engineering applications.

PO_02: Having an ability to design a component or a product applying all the relevant standards and with realistic constraints, including public health, safety, culture, society and environment

PO_03: Having an ability to design and conduct experiments, as well as to analyse and interpret data, and synthesis of information

PO_04: Having an ability to use techniques, skills, resources and modern engineering and IT tools necessary for engineering practice

PO_05: Having problem solving ability- to assess social issues (societal, health, safety, legal and cultural) and engineering problems

PO_06: Having adaptive thinking and adaptability in relation to environmental context and sustainable development

PO_07: Having a clear understanding of professional and

ethical responsibility

PO_08: Having a good cognitive load management skills related to project management and finance

PROGRAMME SPECIFIC OUTCOMES (PSOs)

On completion of M. Tech. (Nanotechnology) programme, graduates will be able to

PSO1: Evolving crucial understanding of Physics & Chemistry of solids, Quantum physics of nanostructures, Nano-electronics and Nano-photonics.

PSO2 : Concentrating on specific skills on Synthesis of nanomaterials, thin film deposition and their characterization.

PSO3: Solve research gaps and provide solutions to socio-economic, and environmental problems.

Category-wise Credit distribution

Category	Credits
University core (UC)	27
Programme core (PC)	19
Programme elective (PE)	18
University elective (UE)	6
Bridge course (BC)	
Total credits	70

Detailed curriculum

(as given in the student curriculum view – in the order of UC, UE, PC and PE). Courses need not be listed under UE.

S. No	Course Code	Course Title	L	Τ	P	J	C
1.	MAT6001	Advanced Statistical Methods	2	0	2	0	3
2.	ENG5001 and ENG5002 (or) EFL5097	Technical English I and Technical English II (or) Foreign Language	{0 0 2	0 0 0	2 2 0	0 0} 0	2
3.	STS5001	Soft Skills	0	0	0	0	1
4.	STS5002	Soft Skills	0	0	0	0	1
5.	SET5001	SET Project-I	0	0	0	0	2
6.	SET5002	SET Project-II	0	0	0	0	2
7.	ECE6099	Master's Thesis	0	0	0	0	16

University Core - 27 Credits

University Elective – 6 Credits

S.No	Course Title	L	Τ	Ρ	J	C
1	University Elective [#]	-	-	-	-	6

All courses offered by other M.Tech Programmes / PE of M.Tech (Nanotechnology)

Programme Core – 19 Credits

S. No	Course Code	Course Title	L	Т	Р	J	C
1	ECE5031	Quantum Physics for Nanostructures	2	0	0	0	2
2	ECE5032	Physics and Chemistry of Solids	2	0	0	0	2
3	ECE5033	Synthesis of Nanomaterials and Thin Film Deposition	2	0	2	4	4
4	ECE 5034	Nanomaterial Characterization Techniques	3	0	2	0	4
5	ECE 6032	Nanoelectronics	2	0	2	4	4
6	ECE 6033	Nanophotonics	3	0	0	0	3

Programme Electives - 18 Credits

S.No	Course Code	Course Title	L	Т	P	J	C
1	ECE 5035	Semiconductor Device Physics	2	0	0	4	3
1	ECE 5055	and Technology					
2	ECE5036	MEMS to NEMS	2	0	0	4	3
4	ECE 5037	Nanosensors	3	0	0	0	3
5	ECE 5038	Carbon Nanomaterials	3	0	0	0	3
6	ECE 5039	Lithographic Techniques for	3	0	0	0	3
0	ECE 5039	Device Fabrication					
7	ECE 5040	Plasmonics	2	0	0	4	3
8	ECE 6031	Nanomagnetism- Fundamentals	3	0	0	0	3
0	ECE 0031	and Applications					
9	ECE 6034	Energy Technologies	3	0	0	0	3
10	ECE 6035	Spintronics	2	0	0	4	3
11	ECE6039	Nanoelectronic Circuit Design	3	0	0	0	3

Syllabus

MAT6001	Course Title			<u>PJ (</u>
	ADVANCED STATISTICAL METHODS	~		203
Pre-requisite	nil	Syllabus	s versio	
				2.
Course Objective				
	udents with a framework that will help them choose the appro	opriate de	escripti	ve
	arious data analysis situations. stributions and relationships of real-time data.			
	mation and testing methods to make inference and modelling t	toohnigu	os for	
	ing using various techniques including multivariate analysis.	techniqu	es 101	
uccision mak	ing using various teeninques including multivariate analysis.			
	Octoor			
Expected Course		ainaanin	~	
	d the value of statistics as a discipline and its relevance for En	0	g	
•	ata using appropriate graphical methods and numerical summand communicate the outcomes of estimation and hypothesis		he con	tovt
of a proble		tests in t		ισλι
-	arge sample test and small sample testing of Hypothesis	as well	as ca	lcula
	e interval for a population parameter for real time data.	us wen	as ca	icuia
	nd verify mathematical considerations for analyzing time serie	es inclue	ting co	ncen
	noise, stationarity, auto-covariance, autocorrelation ; apply			
	s models, including the regression with ARMA models	vario ab	coming	lace
Modulo 1 Basic	Statistical Tools for Analysis:			hou
viouule.1 Dasie	Statistical Tools for Analysis.		-	nou
Summary Statistic	cs, Correlation and Regression, Concept of R^2 and Adjusted R	$\frac{1}{2}$ and a	1 D	:.1
Jummai v Statisti	\mathcal{A} . Conclation and regression. Concept of \mathcal{R}^{-} and Autusted r	<≃ and ar	ia Part	iai ai
-	• •		ia Part	iai ai
Multiple Correlati	ion, Fitting of simple and Multiple Linear regression, Explana legression Diagnostics		ia Part	iai ai
Multiple Correlati	ion, Fitting of simple and Multiple Linear regression, Explana		id Part	
Multiple Correlati Assumptions of R	ion, Fitting of simple and Multiple Linear regression, Explana egression Diagnostics			hou
Multiple Correlations of R Module:2 Statis	ion, Fitting of simple and Multiple Linear regression, Explana tegression Diagnostics tical inference :	tion and	9) hou
Multiple Correlations Assumptions of R Module:2 Statis Basic Concepts, N	ion, Fitting of simple and Multiple Linear regression, Explana egression Diagnostics tical inference : Normal distribution-Area properties, Steps in tests of significant	tion and	9 ge samp	hou
Multiple Correlations Assumptions of R Module:2 Statis Basic Concepts, N ests-Z tests for N	ion, Fitting of simple and Multiple Linear regression, Explana tegression Diagnostics tical inference : Normal distribution-Area properties, Steps in tests of significan leans and Proportions, Small sample tests –t-test for Means, F	tion and	9 ge samp	hou
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Multiple Correlations Assumptions of R Module:2 Statis Basic Concepts, N ests-Z tests for M Variances, Chi-sq	ion, Fitting of simple and Multiple Linear regression, Explana egression Diagnostics tical inference : Normal distribution-Area properties, Steps in tests of significan leans and Proportions, Small sample tests –t-test for Means, F uare test for independence of Attributes.	tion and	9 ge samp Equalit	hou ple ty of
Multiple Correlations Assumptions of R Module:2 Statis Basic Concepts, N Sests-Z tests for M Variances, Chi-sq Module:3 Mode	ion, Fitting of simple and Multiple Linear regression, Explana tegression Diagnostics tical inference : Normal distribution-Area properties, Steps in tests of significan leans and Proportions, Small sample tests –t-test for Means, F uare test for independence of Attributes. Elling and Forecasting Methods:	tion and nce –larg	9 ge samp Equalit 9	hou ble ty of hou
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Multiple Correlations Assumptions of R Module:2 Statis Basic Concepts, N ests-Z tests for N Variances, Chi-sq Module:3 Mode Introduction: Con Smoothing, Linea Moving Averages Probability mode Module:4 Desig Analysis of varian RBD – LSD, Con	ion, Fitting of simple and Multiple Linear regression, Explanal egression Diagnostics tical inference : Normal distribution-Area properties, Steps in tests of significant leans and Proportions, Small sample tests –t-test for Means, Fuare test for independence of Attributes. Elling and Forecasting Methods: Cept of Linear and Non Liner Forecasting model ,Concepts o ar and Compound Growth model, Fitting of Logistic curve and s, Forecasting accuracy tests. Concepts of AR, ARMA and ARIMA model and Forecasting accuracy tests. Concepts of AR, ARMA and ARIMA model and two way classifications – Principle of design of cepts of 22 and 23 factorial experiments temporary issues:	tion and nce –larg test for of Trend, nd their A dels.	9 ge samp Equalit 9 Expon Applica 6 ents, C	hou ble ty of hou hentia ations

Tot	al Lecture hours:		30 hours
Tor	t Book(s)		
	Applied Statistics and Probability for Engineers, 6ed, (2016), Douglas C. M	ontrom	ory Goorgo
1.	C. Runger, John Wiley & Sons	ongom	ery George
2	Time Series Analysis and Its Applications With R Examples (2017), by Shu Stoffer, David S. Springer publications	umway,	Robert H.,
Ref	erence Books		
1.	The Elements of Statistical Learning: Data Mining, Inference, and Predictic (Springer Series in Statistics) (2017), by Trevor Hastie and Robert Tibshiran	i	
2	Introduction to Probability and Statistics: Principles and Applications for E Computing Sciences(2017), Mc.Grawhill education by J. Susan Milton and	-	-
Mo	de of Evaluation		
	Digital Assignments, Quiz, Continuous Assessments, Final Assessm	ent Test	Ţ
List	of Challenging Experiments (Indicative)		
1.	Computing Summary Statistics using real time data		2 hours
2	plotting and visualizing data using Tabulation and Graphical Representations.		2 hours
3	Applying simple linear and multiple linear regression models to real data computing and interpreting the coefficient of determination for scale data		2 hours
4.	Testing of hypothesis for Large sample tests for real-time problems.		2 hours
5.	Testing of hypothesis for Small sample tests for One and Two Sample me and paired comparison (Pre-test and Post-test)	ean	2 hours
6.	Testing of hypothesis for Small Sample tests for F-test		2 hours
7	Testing of hypothesis for Small Sample tests for Chi-square test		2 hours
8	Applying Time series analysis-Trends. Growth ,Logistic, Exponential mo	odels	2 hours
9	Applying Time series model AR ,ARMA and ARIMA and testing Forecasting accuracy tests.		2 hours
10	Performing ANOVA (one-way and two-way), CRD, RBD and LSD for red dataset.	eal	2 hours
11	Performing 22 factorial experiments with real time Applications		2 hours
12	Performing 23 factorial experiments with real time Applications		2 hours
	Total Laboratory	Hours	24 hours
Mo	de of Evaluation	A	

Weekly Assessments, Final Assessment Test						
Recommended by Board of Studies	11-08-2017					
Approved by Academic Council	No.46	Date	24-08-17			

Course code	Course title	L T P J C
ENG5001	Fundamentals of Communication Skills	0 0 2 0 1
Pre-requisite	Not cleared EPT (English Proficiency Test)	Syllabus version
		1.
Course Objective	s:	
1. To enable learne	ers learn basic communication skills - Listening, Speaking, R	eading and Writing
	apply effective communication in social and academic conte	
3. To make studen	ts comprehend complex English language through listening a	nd reading
	0.4	
Expected Course		
	ening and comprehending skills of the learners	
1 1	g skills to express their thoughts freely and fluently	
Ũ	for effective reading	
	cal correct sentences in general and academic writing	
5. Develop technic	al writing skills like writing instructions, transcoding etc.,	
Module:1 Lister		8 hour
	5	0 110U1
Understanding Co Listening to Speec		
Listening for Spec		
Module:2 Speal		4 hour
Exchanging Inform		4 11001
	ies, Events and Quantity	
Module:3 Read		6 hour
Identifying Inform		0 IIOUI
Inferring Meaning		
Interpreting text		
Module:4 Writi	ng: Sentence	8hour
Basic Sentence Str		onour
Connectives		
Transformation of	Sentences	
Synthesis of Sente		
•	ng: Discourse	4hour
Instructions		
Paragraph		
Transcoding		
		30 hour
Total Lecture how	ırs:	
Text Book(s)		
1. Redston, Ch	ris, Theresa Clementson, and Gillie Cunningham. Fa	ace2face Upper
Intermediate S	Student's Book. 2013, Cambridge University Press.	
Reference Books	······································	
1 Chris Juzwiak	Stepping Stones: A guided approach to writing sentences an	nd Paragraphs
	on), 2012, Library of Congress.	-
2. Clifford A W	hitcomb & Leslie E Whitcomb, Effective Interpersonal and T	eam
Communicati	on Skills for Engineers, 2013, John Wiley & Sons, Inc., Hobo	oken: New Jersey.
3. ArunPatil, H	enk Eijkman &Ena Bhattacharya, New Media Commur	

4. 5. 6.	Engineers and IT Professionals,20 Judi Brownell, Listening: Attitudes John Langan, Ten Steps to Impro Press:USA Redston, Chris, Theresa Clements Teacher's Book. 2013, Cambridge Authors, book title, year of publica	s, Principles and S ving College Rea on, and Gillie Cur University Press. ttion, edition numb	kills, 2016 ding Skills nningham. per, press,	5, 5 th Edition, R 5, 2014, 6 th Ed Face2face Up place	ition, Townsend		
Mo	de of Evaluation: CAT / Assignmen	t / Quiz / FAT / P	roject / Sei	ninar			
List	t of Challenging Experiments (Ind	licative)					
1.	ectives with ljective that	2 hours					
2.	Making students identify their pee during presentation and respond u	l Volume	4 hours				
3.	Using Picture as a tool to enhance	learners speaking	and writin	ng skills	2 hours		
4.	Using Music and Songs as tools t language / Activities through VIT	-		he target	2 hours		
5.	Making students upload their Self	- introduction vide	eos in Vim	eo.com	4 hours		
6.	Brainstorming idiomatic expression writings and day to day conversat		em use the	ose in to their	4 hours		
7.	Making students Narrate events b add flavor to their language / Acti		-		4 hours		
8	Identifying the root cause of stage to make their presentation better				4 hours		
9	Identifying common Spelling & S day to day conversations	ting and other	2 hours				
10.	Discussing FAQ's in interviews w better insight in to interviews / Ac	2 hours					
	Total Practical Hours 30 hours						
	de of evaluation: Online Quizzes, Pr i Project	resentation, Role p	olay, Grouj	p Discussions, A	Assignments,		
	Recommended by Board of Studies 22-07-2017						
App	proved by Academic Council	24-8-2017					

Course code	•	Course title	L T P J C
ENG5002		Professional and Communication Skills	0 0 2 0 1
Pre-requisite	e	ENG5001	Syllabus version
			1.1
Course Obje	ectives	:	
1. To enable	studen	ts to develop effective Language and Communication Skills	
2. To enhance	e stud	ents' Personal and Professional skills	
3. To equip the	he stuc	lents to create an active digital footprint	
Expected Co			
-	-	personal communication skills	
		m solving and negotiation skills	
		and mechanics of writing research reports	
		public speaking and presentation skills	
5. Apply the	e acqu	ired skills and excel in a professional environment	
N 1 1 4			
Module:1		onal Interaction	2hours
Introducing (Jnesel	f- one's career goals	
Activity: SW	OT A	nalysis	
J			
Module:2	Inte	rpersonal Interaction	2 hours
Interpersonal		nunication with the team leader and colleagues at the workp	
-			
Activity: Rol	le Play	s/Mime/Skit	
Module:3	Soci	al Interaction	2 hours
		a, Social Networking, gender challenges	2 110 0115
		LinkedIn profile, blogs	
		FF	
Module:4	Rési	ımé Writing	4 hours
Identifying ic	ob rea	airement and key skills	
		n Electronic Résumé	
11001,109,110	<u>pui • u</u>		
Module:5	Inte	rview Skills	4 hours
Placement/Jo	b Inte	rview, Group Discussions	
		erview and mock group discussion	
11001100	•		
Module:6	Ren	ort Writing	4 hours
mouule.o	nep	of the second se	- nouis
Language and	d Mec	hanics of Writing	
Activity. W.	iting o	Report	
Activity: Wri	ning a	Керон	
Module:7	Stud	ly Skills: Note making	2hours
Summarizing		•	I
-	-	Executive Summary, Synopsis	
	uv i,	,~,~,~,~,~,~,~,~,~,~,~,~,~,~,~,~,~	

Module:8	Interpreting skills	2 hours
-	a in tables and graphs	
Activity: Tra	inscoding	
Module:9	Presentation Skills	4 hours
Oral Present	ation using Digital Tools	
Activity: Or	al presentation on the given topic using appropriate non-verbal cues	
Module:10	Problem Solving Skills	4 hours
Problem Sol	ving & Conflict Resolution	I
Activity: Ca	se Analysis of a Challenging Scenario	
1.001/10/100		30hours
	Total Lecture hours	5:
Text Book(a) Igar Nitin and Mamta Bhatnagar, Communicative English For Engine	ors And
	sionals, 2010, Dorling Kindersley (India) Pvt. Ltd.	cis Aliu
Reference I	Books	
	rkman and Christopher Turk, Effective Writing: Improving Scientific ss Communication, 2015, Routledge	, Technical and
	Bairaktarova and Michele Eodice, Creative Ways of Knowing in Er er International Publishing	ngineering, 2017,
	d A Whitcomb & Leslie E Whitcomb, Effective Interperson unication Skills for Engineers, 2013, John Wiley & Sons, Inc., Hobol	
	atil, Henk Eijkman & Ena Bhattacharya, New Media Communic eers and IT Professionals, 2012, IGI Global, Hershey PA.	cation Skills for
Mode of Eva	lluation: CAT / Assignment / Quiz / FAT / Project / Seminar	
	lenging Experiments (Indicative)	
1. SWOT weakn	Y Analysis – Focus specially on describing two strengths and two esses	2 hours
2. Role P	lays/Mime/Skit Workplace Situations	4 hours
	Social Media – Create a LinkedIn Profile and also write a page or areas of interest	2 hours
4. Prepar	e an Electronic Résumé and upload the same in vimeo	2 hours
*	discussion on latest topics	4 hours
	Writing – Real-time reports	2 hours
7 Writin article	g an Abstract, Executive Summary on short scientific or research	4 hours
8 Transc	oding – Interpret the given graph, chart or diagram	2 hours

9	9 Oral presentation on the given topic using appropriate non-verbal cues						
10	10 Problem Solving Case Analysis of a Challenging Scenario				4 hours		
	Total Laboratory Hours						
Mod	le of evaluation: : Online Quizzes,	Presentation, Role	e play, Gro	oup Discussions,	Assignments,		
Mini	i Project						
Reco	ommended by Board of Studies	22-07-2017					
App	roved by Academic Council	No. 47	Date	05-10-2017			

Course code	Course Title		L T P J C
GER5001	Deutsch für Anfänger		2 0 0 0 2
Pre-requisite	NIL	S	yllabus version
			v.1
Course Objective	:		
•	udents the necessary background to:		
	ents to read and communicate in German in their	day to day life	
2. become inc			
3. make them	understand the usage of grammar in the German	Language.	
Expected Course	Outcome:		
The students will b			
1.create the basics	of German language in their day to day life.		
2.understand the co	njugation of different forms of regular/irregular	verbs.	
3.understand the ru	le to identify the gender of the Nouns and apply	articles appropr	riately.
4.apply the Germa	a language skill in writing corresponding letters,	E-Mails etc.	
5.create the talent	f translating passages from English-German and	l vice versa and	To frame
simple dialogues b	ased on given situations.		
Module:1			2 hours
	ana seferman I and shunda Alababat Darsons	lanon on an Ma	3 hours
	sungsformen, Landeskunde, Alphabet, Persona	-	rb Konjugation,
	fragen, Aussagesätze, Nomen – Singular und Pl	ural	
Lernziel:			
Elementares Verst	andnis von Deutsch, Genus- Artikelwörter		
Madada 2			2 h
Module:2	mban (nagalmässig (unnagalmässig) die Manata	dia Washantag	3 hours
	erben (regelmässig /unregelmässig) die Monate, n, Artikel, Zahlen (Hundert bis eine Million), Ja-	•	•
Sie	n, Artikei, Zamen (Hundert dis eine Minion), Ja-	-/Neill- Flage, I	
Lernziel :			
	er Hobbys erzählen, über Berufe sprechen usw.		
bulle bellielbell, ut	er moodys enzumen, uder Derure spreenen usw.		
Module:3			4 hours
	n, Negation, Kasus- AkkusatitvundDativ (best	immter unbest	
-	Modalverben, Adjektive, Uhrzeit, Präposition		
Getränke			
Lernziel :			
	rben, Verwendung von Artikel, über Länder und	d Sprachan apr	ahan jihar aina
Wohnung beschrei		u sprachen spre	chen, uber enie
wonnung beseiner			
Module:4			6 hours
	Peutsch – Englisch / Englisch – Deutsch)		
Lernziel :			
Grammatik – Wor	schatz – Übung		
•			
Module:5			5 hours
	indmap machen,Korrespondenz- Briefe, Postkar	ten, E-Mail	5 hours

117	. 1		1 1			
WO	rtschatz	bildung und aktiver Sprach	gebrauch			
Mo	dule:6					3 hours
	sätze :	•				5 110015
		versität, Das Essen, mein Fre	und oder meine F	roundin n	aina Familia ai	n Fast in
	itschlan			iculiulii, li	cine r'annie, er	n rest m
Deu	useman	u usw				
Mo	dule:7					4 hours
Dia	loge:	l			I	
	0	präche mit Familienmitglied	lern, Am Bahnhof	•		
		präche beim Einkaufen ; in (Buchhandlung ;	
	· ·	nem Hotel - an der Rezeptio	-			
	ffen im	-	,			
Mo	dule:8					2 hours
Gue	est Lect	ures/Native Speakers / Feir	nheiten der deutso	chen Sprac	he, Basisinform	nation über die
deut	tschspra	chigen Länder		-		
		0		Total L	ecture hours:	30 hours
Tex	t Book	(s)				
1.		d A1 Deutsch als Fren	ndsprache, Hern	nann Fun	k, Christina K	Kuhn, Silke
		e : 2012	• /		,	,
Ref	erence	Books				
1	Netzw	erk Deutsch als Fremdsprach	he A1, Stefanie De	engler, Pau	ll Rusch, Helen	Schmtiz, Tanja
	Sieber,					
2	Lagune	e,Hartmut Aufderstrasse, Ju	utta Müller, Thom	as Storz, 2	012.	
3	Deutsc	he SprachlehrefürAUslände	r, Heinz Griesbach	h, Dora Sc	hulz, 2011	
4	Theme	nAktuell 1, HartmurtAufder	strasse, Heiko Bo	ck, Mechtl	nildGerdes, Jutta	ı Müller und
		t Müller, 2010				
	-	goethe.de				
		aftsdeutsch.de				
	hueber	.de				
	klett-sp	prachen.de				
		eutschtraning.org				
		valuation: CAT / Assignmen		/ FAT		
		ded by Board of Studies	04-03-2016	-	I	
App	proved b	y Academic Council	41	Date	17-06-2016	

Course coo	de Course Title		T P J C
FRE5001	FRANCAIS FONCTIONNEL	2	0 0 0 2
Pre-requisite	e Nil	Sylla	bus versior
			1.0
Course Obje			
1. demoi knowl sports	ves students the necessary background to: nstrate competence in reading, writing, and speaking basic edge of vocabulary (related to profession, emotions, /hobbies, classroom and family). /e proficiency in French culture oriented view point.		
Evnootod Co	urse Outcome:		
-	will be able to		
prono 2. create 3. demon senten 4. unders writte	nber the daily life communicative situations via personal pronou- uns, salutations, negations, interrogations etc. communicative skill effectively in French language via regular / nstrate comprehension of the spoken / written language in transla- nces. stand and demonstrate the comprehension of some particular new n materials. nstrate a clear understanding of the French culture through the lat	/ irregula ating sim v range c	r verbs. ple of unseen
J. defilor	istrate a clear understanding of the French culture through the la	nguage s	tuulcu.
Les Salutation Sujets, Les P	Saluer, Se présenter, Etablir des contacts ns, Les nombres (1-100), Les jours de la semaine, Les mois de l ronoms Toniques, La conjugaison des verbes réguliers, La con		Les Pronom
Les Salutation Sujets, Les P irréguliers- av Module:2	ns, Les nombres (1-100), Les jours de la semaine, Les mois de l ronoms Toniques, La conjugaison des verbes réguliers, La con roir / être / aller / venir / faire etc. Présenter quelqu'un, Chercher un(e) correspondant(e), Den	njugaisoi	Les Pronom 1 des verbe
Les Salutation Sujets, Les P irréguliers- av Module:2	ns, Les nombres (1-100), Les jours de la semaine, Les mois de l ronoms Toniques, La conjugaison des verbes réguliers, La con voir / être / aller / venir / faire etc.	njugaisoi	Les Pronom 1 des verbe
Les Salutation Sujets, Les P irréguliers- av Module:2	ns, Les nombres (1-100), Les jours de la semaine, Les mois de l ronoms Toniques, La conjugaison des verbes réguliers, La con roir / être / aller / venir / faire etc. Présenter quelqu'un, Chercher un(e) correspondant(e), Den	njugaisoi	Les Pronom n des verbe 3 hour
Les Salutation Sujets, Les P irréguliers- av Module:2	ns, Les nombres (1-100), Les jours de la semaine, Les mois de l ronoms Toniques, La conjugaison des verbes réguliers, La con voir / être / aller / venir / faire etc. Présenter quelqu'un, Chercher un(e) correspondant(e), Den des nouvelles d'une personne. njugaison des verbes Pronominaux, on avec 'Est-ce que ou sans Est-ce que'.	njugaison nander	
Les Salutation Sujets, Les P irréguliers- av Module:2	ns, Les nombres (1-100), Les jours de la semaine, Les mois de l ronoms Toniques, La conjugaison des verbes réguliers, La con voir / être / aller / venir / faire etc. Présenter quelqu'un, Chercher un(e) correspondant(e), Den des nouvelles d'une personne.	njugaison nander La), L'artic l'adject	Les Pronom n des verbes 3 hour Négation 4 hour le contracté if possessif
Les Salutation Sujets, Les P irréguliers- av Module:2 1 La con L'interrogation Module:3 S L'article (déf Les heures e l'adjectif dér adjectifs avec	ns, Les nombres (1-100), Les jours de la semaine, Les mois de l ronoms Toniques, La conjugaison des verbes réguliers, La con voir / être / aller / venir / faire etc. Présenter quelqu'un, Chercher un(e) correspondant(e), Den des nouvelles d'une personne. njugaison des verbes Pronominaux, on avec 'Est-ce que ou sans Est-ce que'. Situer un objet ou un lieu, Poser des questions ini/ indéfini), Les prépositions (à/en/au/aux/sur/dans/avec etc.) en français, La Nationalité du Pays, L'adjectif (La Couleur, nonstratif/ l'adjectif interrogatif (quel/quelles/quelle/qu	njugaison nander La , L'artic l'adject telles), I	Les Pronom n des verbes 3 hour Négation 4 hour le contracté if possessif
Les Salutation Sujets, Les P irréguliers- av Module:2 1 La con L'interrogation Module:3 S L'article (déf Les heures e l'adjectif dér adjectifs avec	ns, Les nombres (1-100), Les jours de la semaine, Les mois de l ronoms Toniques, La conjugaison des verbes réguliers, La con /oir / être / aller / venir / faire etc. Présenter quelqu'un, Chercher un(e) correspondant(e), Den des nouvelles d'une personne. njugaison des verbes Pronominaux, on avec 'Est-ce que ou sans Est-ce que'. Situer un objet ou un lieu, Poser des questions ini/ indéfini), Les prépositions (à/en/au/aux/sur/dans/avec etc.) en français, La Nationalité du Pays, L'adjectif (La Couleur, nonstratif/ l'adjectif interrogatif (quel/quelles/quelle/qu le nom, L'interrogation avec Comment/ Combien / Où etc., Faire des achats, Comprendre un texte court, Deman	njugaison nander La , L'artic l'adject telles), I	Les Pronom n des verbes 3 hour Négation 4 hour le contracté if possessif c'accord des
Les Salutation Sujets, Les P irréguliers- av Module:2 1 La con L'interrogation Module:3 S L'article (déf Les heures e l'adjectif dér adjectifs avec Module:4 1 La traduction	ns, Les nombres (1-100), Les jours de la semaine, Les mois de l ronoms Toniques, La conjugaison des verbes réguliers, La con /oir / être / aller / venir / faire etc. Présenter quelqu'un, Chercher un(e) correspondant(e), Den des nouvelles d'une personne. njugaison des verbes Pronominaux, on avec 'Est-ce que ou sans Est-ce que'. Situer un objet ou un lieu, Poser des questions ini/ indéfini), Les prépositions (à/en/au/aux/sur/dans/avec etc.) en français, La Nationalité du Pays, L'adjectif (La Couleur, nonstratif/ l'adjectif interrogatif (quel/quelles/quelle/qu le nom, L'interrogation avec Comment/ Combien / Où etc., Faire des achats, Comprendre un texte court, Demandindiquer le chemin. simple :(français-anglais / anglais –français) Trouver les questions, Répondre aux questions générales en	njugaison nander La , L'artic l'adject telles), I	Les Pronom n des verbe 3 hour Négation 4 hour le contracté if possessif .'accord de 6 hour
Les Salutation Sujets, Les P irréguliers- av Module:2	ns, Les nombres (1-100), Les jours de la semaine, Les mois de l ronoms Toniques, La conjugaison des verbes réguliers, La con /oir / être / aller / venir / faire etc. Présenter quelqu'un, Chercher un(e) correspondant(e), Den des nouvelles d'une personne. njugaison des verbes Pronominaux, on avec 'Est-ce que ou sans Est-ce que'. Situer un objet ou un lieu, Poser des questions ini/ indéfini), Les prépositions (à/en/au/aux/sur/dans/avec etc.) en français, La Nationalité du Pays, L'adjectif (La Couleur, nonstratif/ l'adjectif interrogatif (quel/quelles/quelle/qu le nom, L'interrogation avec Comment/ Combien / Où etc., Faire des achats, Comprendre un texte court, Demandindiquer le chemin. simple :(français-anglais / anglais –français) Trouver les questions, Répondre aux questions générales en français.	njugaison nander La), L'artic l'adject lelles), L der et	Les Pronom n des verbe 3 hour Négation 4 hour le contracté if possessif de contracté 5 hour
Les Salutation Sujets, Les P irréguliers- av Module:2 1 La con L'interrogatio Module:3 S L'article (déf Les heures e l'adjectif dér adjectifs avec Module:4 1 La traduction Module:5 7	ns, Les nombres (1-100), Les jours de la semaine, Les mois de l ronoms Toniques, La conjugaison des verbes réguliers, La con /oir / être / aller / venir / faire etc. Présenter quelqu'un, Chercher un(e) correspondant(e), Den des nouvelles d'une personne. njugaison des verbes Pronominaux, on avec 'Est-ce que ou sans Est-ce que'. Situer un objet ou un lieu, Poser des questions ini/ indéfini), Les prépositions (à/en/au/aux/sur/dans/avec etc.) en français, La Nationalité du Pays, L'adjectif (La Couleur, nonstratif/ l'adjectif interrogatif (quel/quelles/quelle/qu le nom, L'interrogation avec Comment/ Combien / Où etc., Faire des achats, Comprendre un texte court, Demandindiquer le chemin. simple :(français-anglais / anglais –français) Trouver les questions, Répondre aux questions générales en	njugaison nander La , L'artic l'adject der et der et	Les Pronom n des verbe 3 hour Négation 4 hour le contracté if possessif de contracté 5 hour

Mo	dule:6	Comment ecrire un pass	age			3 hours
Déc	crivez :					
La	Famille /	/La Maison, /L'université /I	Les Loisirs/ La Vie	e quotidier	nne etc.	
	dule:7	Comment ecrire un diale	ogue			4 hours
	logue:					
	/	erver un billet de train				
	,	e deux amis qui se rencontr				
	/	ni les membres de la famille	2			
	g) Ent	re le client et le médecin				
	110	T • / 1 / T 11 NT / •	•			
Mo	dule:8	Invited Talk: Native spo	eakers			2 hours
				Tot	al Lecture hours:	30 hours
				100	al Lecture nours.	50 110015
Tor	t Book(a)				
1.		s) , Méthode de français, J. Gi	rardet I Décheur	Publisher	r CI E International	Paris 2010
2		, Cahier d'exercices, J. Gira				
_	erence l					d115 2010.
1.		EXIONS 1, Méthode de fra	ncais. Régine Mé	rieux. Yve	es Loiseau.Les Éditio	ons Didier.
	2004.	- ··- , ··· ··· ··	<i>z</i> , 8		·····, ····	
2	CONN	EXIONS 1, Le cahier d'ex	ercices, Régine M	lérieux, Yv	ves Loiseau, Les Éd	itions
	Didier,	2004.				
3	ALTE	R EGO 1, Méthode de franç	cais, Annie Berthe	et, Catherin	ne Hugo, Véronique	М.
	Kiziria	n, Béatrix Sampsonis, Mon	ique Waendendrie	s, Hachet	te livre 2006.	
		-				
Mo	de of Ev	aluation: CAT / Assignmen	t / Quiz / Seminar	:/ FAT		
		led by Board of Studies	26.02.2016			
App	proved b	y Academic Council	No.41	Date	17-06-2016	

Course code		Course Title				L	T	P J	C
SET 5001	SCIENCE, EN	GINEERING AN	D TECH	NOLOGY					2
		PROJECT-	[
Pre-requisite					Syl	labı	us V	Versi	on
Anti-requisite									1.10
Course Objectives	:								
 To inculcate 	opportunity to involve research culture the rational and inno			e / enginee	ring				
1. Identify pro	his course, the studen blems that have relev	ance to societal / i		eeds					
	pendent thinking and the application of re	•	gineering	principles					
Modalities / Requi	rements								
1. Individual o	r group projects can l	be taken up							
2. Involve in li	terature survey in the	e chosen field							
3. Use Science	/Engineering princip	les to solve identif	ied issues						
4. Adopt releva	ant and well-defined	/ innovative metho	dologies to	o fulfill the	spec	ifie	d ol	bject	ive
5. Submission	of scientific report in	a specified forma	t (after plag	giarism che	eck)				
Student Assessmer	nt : Periodical review	s, oral/poster pres	entation						
Recommended by H	Board of Studies	17-08-2017							
Approved by Acade	emic Council	No. 47	Date	05-10-201	17				

Course code		Course Title				L	Т	Ρ.	J C
SET 5002	SCIENCE, EN	GINEERING AN PROJECT- I		OLOGY					2
Pre-requisite					Syll	labı	is V	⁷ ers	ion
Anti-requisite									1.10
Course Objectives	•								
2. To incul	ide opportunity to inv cate research culture nce the rational and in			-	ineeri	ing			
Expected Course (On completion of th	Dutcome: his course, the studen	t should be able to	:			<u> </u>		<u> </u>	
-	oblems that have rele			aada					
• •	lependent thinking an		muusuiai i	iecus					
	te the application of r	•	ngineering	principles					
0. 20. 10. 10. 10. 10. 10. 10. 10. 10. 10. 1				principios					
Modalities / Requi	rements								
	al or group projects c	can be taken up							
	in literature survey in	-							
3. Use Scie	ence/Engineering prir	nciples to solve ide	ntified issu	les					
4. Adopt r	relevant and well-de	efined / innovativ	e methodo	ologies to	fulfil	ll tl	he	spea	cified
objective	e			-				-	
5. Submiss	sion of scientific repo	rt in a specified for	mat (after	plagiarism	chec	k)			
Student Assessmer	nt : Periodical review	vs, oral/poster prese	entation						
Recommended by H	Board of Studies	17-08-2017							
Approved by Acade	emic Council	No. 47	Date	05-10-201	17				

	e	Course title		P J C
STS 5001		Essentials of Business Etiquette and problem solving	3 0 0	0 0 1
Pre-requisi	te	None	Syllabus	version
Course Ob	iaatiyaa			
Course Obj 1. To d		: the students' logical thinking skills		
	-	strategies of solving quantitative ability problems		
		e verbal ability of the students		
		critical thinking and innovative skills		
Expected C				
		dents to use relevant aptitude and appropriate language to exp	press them	selves
		icate the message to the target audience clearly will be able to be proficient in solving quantitative aptitude a	and varbal	ability
		various examinations effortlessly		aonn y
qaes				
Module:1	Busine	ess Etiquette: Social and Cultural Etiquette and Writing		9 hours
	Compa	any Blogs and Internal Communications and Planning and	d	
	Writin	g press release and meeting notes		
		stoms, Language, Tradition, Building a blog, Developing bra		ge,
-	-	ompetition, Open and objective Communication, Two way di	-	lastina
		udience, Identifying, Gathering Information, Analysis, Deter , Types of planning, Write a short, catchy headline, Get to th		lecting
	iss encer			
		ject in the first paragraph., Body – Make it relevant to your a		
Module:2	your sub		udience,	3 hours
Module:2 Prioritizatio	your sub Study n, Procr	oject in the first paragraph., Body – Make it relevant to your a skills – Time management skills rastination, Scheduling, Multitasking, Monitoring, working u	udience,	
Module:2	your sub Study n, Procr	oject in the first paragraph., Body – Make it relevant to your a skills – Time management skills rastination, Scheduling, Multitasking, Monitoring, working u	udience,	
Module:2 Prioritizatio adhering to	your sub Study n, Procr deadline	oject in the first paragraph., Body – Make it relevant to your a skills – Time management skills astination, Scheduling, Multitasking, Monitoring, working un es	nder press	ure and
Module:2 Prioritizatio adhering to	your sub Study n, Procr deadline Presen	oject in the first paragraph., Body – Make it relevant to your a skills – Time management skills astination, Scheduling, Multitasking, Monitoring, working us es	nder press	
Module:2 Prioritizatio adhering to	your sub Study n, Procr deadline Presen materi	oject in the first paragraph., Body – Make it relevant to your a skills – Time management skills astination, Scheduling, Multitasking, Monitoring, working un es	nder press	ure and
Module:2 Prioritizatio adhering to Module:3	your sub Study n, Procr deadline Presen materi with q	oject in the first paragraph., Body – Make it relevant to your a skills – Time management skills astination, Scheduling, Multitasking, Monitoring, working un es atation skills – Preparing presentation and Organizing fals and Maintaining and preparing visual aids and Dealin uestions	nder press	ure and
Module:2 Prioritizatio adhering to Module:3	your sub Study n, Procr deadline Presen materi with q orepare H	opject in the first paragraph., Body – Make it relevant to your a skills – Time management skills astination, Scheduling, Multitasking, Monitoring, working uses atation skills – Preparing presentation and Organizing als and Maintaining and preparing visual aids and Dealing DeverPoint presentation, Outlining the content, Passing the E	nder press	ure and 7 hours st, Blue
Module:2 Prioritizatio adhering to Module:3 10 Tips to p sky thinkin	your sub Study n, Procr deadline Presen materi with q orepare F ag, Intro	opject in the first paragraph., Body – Make it relevant to your a skills – Time management skills rastination, Scheduling, Multitasking, Monitoring, working uses rastination skills – Preparing presentation and Organizing rals and Maintaining and preparing visual aids and Dealing uestions PowerPoint presentation, Outlining the content, Passing the E poduction , body and conclusion, Use of Font, Use of	nder press	ure and 7 hours st, Blue trategic
Module:2 Prioritizatio adhering to Module:3 10 Tips to p sky thinkin presentation	your sub Study n, Procr deadline Presen materi with q prepare F ng, Intro	oject in the first paragraph., Body – Make it relevant to your a skills – Time management skills astination, Scheduling, Multitasking, Monitoring, working uses atation skills – Preparing presentation and Organizing als and Maintaining and preparing visual aids and Dealing uestions PowerPoint presentation, Outlining the content, Passing the E oduction , body and conclusion, Use of Font, Use of tance and types of visual aids, Animation to captivate your au	nder press	ure and 7 hours st, Blue trategic esign of
Module:2 Prioritizatio adhering to Module:3 10 Tips to p sky thinkin presentation posters, Set	your sub Study n, Procr deadline Presen materi with q prepare F ng, Intro n, Import tting ou	opject in the first paragraph., Body – Make it relevant to your a skills – Time management skills rastination, Scheduling, Multitasking, Monitoring, working uses rastination skills – Preparing presentation and Organizing rals and Maintaining and preparing visual aids and Dealing uestions PowerPoint presentation, Outlining the content, Passing the E poduction , body and conclusion, Use of Font, Use of	nder press	ure and 7 hours st, Blue trategic esign of
Module:2 Prioritizatio adhering to Module:3 10 Tips to p sky thinkin presentation posters, Set	your sub Study n, Procr deadline Presen materi with q prepare F ng, Intro n, Import tting ou	oject in the first paragraph., Body – Make it relevant to your a skills – Time management skills rastination, Scheduling, Multitasking, Monitoring, working uses ratation skills – Preparing presentation and Organizing rals and Maintaining and preparing visual aids and Dealing uestions PowerPoint presentation, Outlining the content, Passing the E oduction , body and conclusion, Use of Font, Use of tance and types of visual aids, Animation to captivate your au t the ground rules, Dealing with interruptions, Staying i	nder press	ure and 7 hours st, Blue trategic esign of
Module:2 Prioritizatio adhering to Module:3 10 Tips to p sky thinkin presentation posters, Set	your sub Study n, Procr deadline Presen materi with q orepare F ng, Intro n, Import tting ou Handling	oject in the first paragraph., Body – Make it relevant to your a skills – Time management skills rastination, Scheduling, Multitasking, Monitoring, working uses ratation skills – Preparing presentation and Organizing rals and Maintaining and preparing visual aids and Dealing uestions PowerPoint presentation, Outlining the content, Passing the E oduction , body and conclusion, Use of Font, Use of tance and types of visual aids, Animation to captivate your au t the ground rules, Dealing with interruptions, Staying i	nder press nder press ng levator Te Color, S ndience, Do in control	ure and 7 hours st, Blue trategic esign of of the
Module:2 Prioritizatio adhering to Module:3 10 Tips to p sky thinkin presentation posters, Set questions, H	your sub Study n, Procr deadline Presen materi with q orepare H ag, Intro a, Import tting ou Handling	oject in the first paragraph., Body – Make it relevant to your a skills – Time management skills astination, Scheduling, Multitasking, Monitoring, working uses tation skills – Preparing presentation and Organizing tals and Maintaining and preparing visual aids and Dealing uestions PowerPoint presentation, Outlining the content, Passing the E oduction , body and conclusion, Use of Font, Use of tance and types of visual aids, Animation to captivate your au t the ground rules, Dealing with interruptions, Staying i difficult questions	nder press nder press ng levator Te Color, S ndience, Do in control	ure and 7 hours st, Blue trategic esign of of the
Module:2 Prioritizatio adhering to Module:3 10 Tips to p sky thinkin presentation posters, Set questions, H Module:4	your sub Study n, Procr deadline Presen materi with q orepare F ng, Intro n, Import tting ou Handling Quant Progre	oject in the first paragraph., Body – Make it relevant to your a skills – Time management skills astination, Scheduling, Multitasking, Monitoring, working uses astination skills – Preparing presentation and Organizing als and Maintaining and preparing visual aids and Dealing uestions PowerPoint presentation, Outlining the content, Passing the E boduction , body and conclusion, Use of Font, Use of tance and types of visual aids, Animation to captivate your au t the ground rules, Dealing with interruptions, Staying is difficult questions	nder press nder press ng levator Te Color, S idience, Do in control	ure and 7 hours st, Blue trategic esign of of the 1 hours
Module:2 Prioritizatio adhering to Module:3 10 Tips to p sky thinkin presentation posters, Set questions, H Module:4 Number of	your sub Study n, Procr deadline Presen materi with q orepare F ag, Intro a, Import tting ou Handling Quant Progre factors	skills – Time management skills astination, Scheduling, Multitasking, Monitoring, working under skills – Time management skills astination, Scheduling, Multitasking, Monitoring, working under station skills – Preparing presentation and Organizing tals and Maintaining and preparing visual aids and Dealing uestions PowerPoint presentation, Outlining the content, Passing the E boduction , body and conclusion, Use of Font, Use of tance and types of visual aids, Animation to captivate your au t the ground rules, Dealing with interruptions, Staying i difficult questions itative Ability -L1 – Number properties and Averages and essions and Percentages and Ratios , Factorials, Remainder Theorem, Unit digit position, Ter	nder press nder press ng levator Te Color, S ndience, Da in control	ure and 7 hours st, Blue trategic esign of of the 1 hours
Module:2 Prioritizatio adhering to Module:3 10 Tips to p sky thinkin presentation posters, Set questions, H Module:4 Number of Averages,	your sub Study n, Procr deadline Presen materi with q orepare H ag, Intro n, Import tting ou landling Quant Progre	oject in the first paragraph., Body – Make it relevant to your a skills – Time management skills astination, Scheduling, Multitasking, Monitoring, working uses astination skills – Preparing presentation and Organizing als and Maintaining and preparing visual aids and Dealing uestions PowerPoint presentation, Outlining the content, Passing the E boduction , body and conclusion, Use of Font, Use of tance and types of visual aids, Animation to captivate your au t the ground rules, Dealing with interruptions, Staying is difficult questions	nder press nder press ng levator Te Color, S idience, De in control d 1 ns digit p ession, Ha	ure and 7 hours st, Blue trategic esign of of the 1 hours

Mo	dule:5	Reasoning Ability-L1 – Analytical Reasoning	8 hours			
		gement (Linear and circular & Cross Variable Relationship), Blood Relationship, Blood Relationship/grouping, Puzzle test, Selection Decision table	ns,			
Мо	Module:6 Verbal Ability-L1 – Vocabulary Building					
•	•	& Antonyms, One-word substitutes, Word Pairs, Spellings, Idioms, Sente h, Analogies	nce			
		Total Lecture hours:	45 hours			
Ref	erence 1	Books				
1.	Tools f	Patterson, Joseph Grenny, Ron McMillan, Al Switzler (2001) Crucial Conv For Talking When Stakes are High. Bangalore. McGraw-Hill Contemporary	y			
2.	Dale C Books	Carnegie, (1936) How to Win Friends and Influence People. New York	k. Gallery			
3.	Scott P	eck. M (1978) Road Less Travelled. New York City. M. Scott Peck.				
4.	FACE	(2016) Aptipedia Aptitude Encyclopedia. Delhi. Wiley publications				
5.	ETHN	US (2013) Aptimithra. Bangalore. McGraw-Hill Education Pvt. Ltd.				
We	bsites:					
1.	<u>www.c</u>	halkstreet.com				
2.	www.s	killsyouneed.com				
3.	www.n	nindtools.com				
4.	www.t	hebalance.com				
5.	www.e	2 <u>uru.000</u>				
		valuation: FAT, Assignments, Projects, Case studies, Role plays, nts with Term End FAT (Computer Based Test)				

Course code	Course title	L T P J C
STS 5002	Preparing for Industry	3 0 0 0 1
Pre-requisite	None	Syllabus version
Course Objectives:	 To challenge students to explore their problem-solvin To develop essential skills to tackle advance quantitat ability questions To have working knowledge of communicating in En 	tive and verbal
Expected Course Outcome:	 Enabling students to simplify, evaluate, analyze and u expressions to simulate real situations to be industry r The students will be able to interact confidently and use of models effectively The students will be able to be proficient in solving q aptitude and verbal ability questions of various examineffortlessly 	eady. lecision making uantitative
Module:1	Interview skills – Types of interview and Techniques to face remote interviews and Mock Interview	3 hours
Interviewers' persp	ructured interview orientation, Closed questions and hypotheti ective, Questions to ask/not ask during an interview, Video int Phone interview preparation, Tips to customize preparation for rounds	erview
Module:2	Resume skills – Resume Template and Use of power verbs and Types of resume and Customizing resume	2 hours
Quiz on types of a	dard resume, Content, color, font, Introduction to Power ver resume, Frequent mistakes in customizing resume, Layout requirement, Digitizing career portfolio	1 '
Module:3	Emotional Intelligence - L1 – Transactional Analysis and Brain storming and Psychometric Analysis and Rebus Puzzles/Problem Solving	12 hours
Brainstorming, Step brainstorming, Sta	tracting, ego states, Life positions, Individual Brains pladder Technique, Brain writing, Crawford's Slip writing a r bursting, Charlette procedure, Round robin brainstorm ore than one answer, Unique ways	oproach, Reverse
Module:4	Quantitative Ability-L3 – Permutation-Combinations and Probability and Geometry and mensuration and Trigonometry and Logarithms and Functions and Quadratic Equations and Set Theory	14 hours
Independent and De	lg, Linear Arrangement, Circular Arrangements, Condition ependent Events, Properties of Polygon, 2D & 3D Figures, A ces, Simple trigonometric functions, Introduction to logarithm	Area & Volumes,

iogannins, mut	oduction to functions, Basic rules of functions, Understan	ding Quadratic
Equations, Rules	& probabilities of Quadratic Equations, Basic concepts of Venn I	Diagram
		-
Module:5	Reasoning ability-L3 – Logical reasoning and Data	7 hours
	Analysis and Interpretation	
Syllogisms, Binar	ry logic, Sequential output tracing, Crypto arithmetic, Data Suffic	iency, Data
interpretation-Ad	vanced, Interpretation tables, pie charts & bar chats	
Module:6	Verbal Ability-L3 – Comprehension and Logic	7 hours
Total Lecture ho		
		15 hours
		45 hours
References	 Michael Farra and JIST Editors(2011) Quick Resume Book: Write and Use an Effective Resume in Just One Paul, Minnesota. Jist Works Daniel Flage Ph.D(2003) The Art of Questioning: An Critical Thinking. London. Pearson FACE(2016) Aptipedia Aptitude Encyclopedia.Delhi. 	& Cover Letter Day. Saint Introduction to
References	 Michael Farra and JIST Editors(2011) Quick Resume Book: Write and Use an Effective Resume in Just One Paul, Minnesota. Jist Works Daniel Flage Ph.D(2003) The Art of Questioning: An Critical Thinking. London. Pearson 	& Cover Letter Day. Saint Introduction to

Course Code	Course Title	L	Т	Р	J	С
ECE6099	09 Masters Thesis		0	0	0	16
Pre-requisite	As per the academic regulations	Syllabus versio			sion	
		1.0				

Course Objectives:

To provide sufficient hands-on learning experience related to the design, development and analysis of suitable product / process so as to enhance the technical skill sets in the chosen field.

Expected Course Outcome:

At the end of the course the student will be able to

- 1. Formulate specific problem statements for ill-defined real life problems with reasonable assumptions and constraints.
- 2. Perform literature search and / or patent search in the area of interest.
- 3. Conduct experiments / Design and Analysis / solution iterations and document the results.
- 4. Perform error analysis / benchmarking / costing
- 5. Synthesise the results and arrive at scientific conclusions / products / solution
- 6. Document the results in the form of technical report / presentation

Contents

Capstone Project may be a theoretical analysis, modeling & simulation, experimentation & analysis, prototype design, fabrication of new equipment, correlation and analysis of data, software development, applied research and any other related activities.

Project should be for two semesters based on the completion of required number of credits as per the academic regulations.

Should be individual project.

In case of group projects, the individual project report of each student should specify the individual's contribution to the group project.

Carried out inside or outside the university, in any relevant industry or research institution.

Publications in the peer reviewed journals / International Conferences will be an added advantage

Mode of Evaluation: Periodic reviews, Presentation, Final oral viva, Poster submission							
Recommended by Board of	10-06-2015						
Studies							
Approved by Academic Council	No. 37	Date	16-06-2015				

Course Code	Course Title	LT	P	JC	1
ECE5031		$\frac{1}{2}$ 0	0	$\frac{0}{0}$ 2	Ĵ
Pre-requisite	Nil	2 0	V	0 2	<u> </u>
1 re-requisite					
Course Objecti	ve:				
The course is air					
1. Educate	various concepts of quantum theory and its importance.				
	em understand the different quantum nanostructures and their den	sity of	state	s.	
	iem to apply quantum theory to design nanoscale devices.	·			
Expected Cours	se Outcomes:				
Students will be	able to:				
1. Gain the	advanced concepts of quantum theory.				
	nd the importance of Schrodinger wave equation & its application	ns.			
3. Obtain th	e knowledge on quantum confinement effects.				
4. Gain the	knowledge in dispersion relation of electron in solids.				
	nd the quantum nanostructures, such as quantum dots, nanowi	res an	d qua	antun	n
	their density of states.				
	nd the time-dependent perturbation and its applications.				
Module :1 Int			4 hou		
	uantum theory, Wave-particles duality, de-Broglie and Fermi Wa				
	nical operators, Uncertainty principle, Quantum numbers and	Hydro	ogen	ator	n
problem, Pauli e	xclusion principle.				
	rodinger equations and their formulation		3 hou	irs	
Schrödinger time	e dependent and time independent wave equations - analytical sol	utions	•		
Module:3 Pot	contial Wall Detential Domian and Tunnelling		4 hou	1 100	
	tential Well, Potential Barrier and Tunnelling al Potential well, Particle in 1D, 2D and 3D box, Rectangular Ba				f
	ectance, transmittance and tunnelling probability, Scanning tunnel				
Tunnening, Kerk	cetalee, transmittance and tunnering probability, Seaming tunner	inng n	neros	cope	
Module:4 Th	eory of conduction in solids		4 hou	irs	
	he theory of Conduction in Solids -Drude model, Nearly free				Ι.
Dispersion relati					,
1					
Module:5 Ele	ctronic Band Structure		5 hou	ırs	
	Brillouine zones, Periodic potential, Bloch Theorem, Kronig-Per				d
	y bands, direct and indirect gap semiconductors.				
8					
Module:6 Qu	antum Confinement and Density of States		4 hou	ırs	
	ntum Confinement, Quantum Dots, Quantum Well and Quantum	ı Wire	s, D	ensity	y
	2D, 1D and 0D solid, carrier concentration.				
,					
Module:7 Tir	ne-dependent perturbation and applications		4 hou	ırs	
Time-dependent	change in potential, First-order time-dependent perturbation, Fer	mi's g	older	n rule	;,
Photon emission	n due to electronic transitions, Fermi's golden rule for st	imulat	ed o	ptica	1
transitions, Semi	conductor laser.				
Module:8 Co	ntemporary issues:		2 hou	ırs	
	· ·				

			Total Lee	cture:	30 hours		
Tex	t Book(s)						
1	A. F. J. Levi, Applied Quantu	m Mechanics, Secon	d edition, Cambri	dge Un	iversity Press,		
	2006.	5.					
2	Richard L. Liboff, Introductory	Quantum Mechanics	, Fourth edition, P	earson l	Education Inc,		
	India, 2003.						
Ref	erence Books						
1	Robert Eisberg and Robert Res	nick, Quantum Physic	es of Atoms, Mole	ecules, S	Solids, Nuclei,		
	and Particles, second Edition, Jo	ohn Wiley & Sons, Ca	nada, 1985.				
2	A. Ghatak and S. Lokanathan, G	Quantum Mechanics-7	Theory & Applicat	ions, M	acmillan India		
	Limited, New Delhi, 2002.						
3	A. Beiser, Concepts of Modern	Physics, Sixth edition	, TataMcGraw- Hi	ll Editio	on, New Delhi,		
	2003.						
Mo	de of Evaluation: Continuous As	sessment Test –I (CA	Γ-I) , Continuous A	Assessm	ent Test –II		
(CA	AT-II), Seminar / Challenging As	signments / Completio	on of MOOC / QU	IZ, Fina	l Assessment		
Tes	t (FAT).						
Rec	commended by Board of Studies	13-12-2015					
App	proved by Academic Council	No. 40	Date	18-03-2	2016		

Course Cod	e Course Title	
ECE5032	PHYSICS AND CHEMISTRY OF SOLIDS	
Pre-requisit		
110 requisit		
Course Obj	ectives:	
The course is		
1. Provi	de understanding of properties of materials from an atomistic view	v point, and to
classi	fy solids.	
	ne the properties and structure of crystalline materials, various mode	s of bonding in
	with appropriate examples.	
	er them about thermodynamics and statistical mechanics of solids.	
	ourse Outcomes:	
Students will		
	knowledge on crystal structure	
	rstand various types of atomic bonding in solids.	
	ify the materials based on their properties. Ify different imperfections in solids.	
	rstand thermodynamics and elementary statistical mechanics.	
	Magnetic, Optical & Thermal properties of different materia	l for potential
	cations.	i ioi potentiai
11	Structure of Matter	6 hours
Crystal stru	cture & Bonding- Crystals, Polycrystals, Symmetry, Unit cells, E	Bravais lattices,
	ohic directions, Crystallographic planes, Miller indices, Bragg's law	
	X-ray diffraction.	
Module 2	Chemical Bonding	3 hours
Atomic Bon	ling in solids - Types of bond: Metallic, Ionic, Covalent and van d	er Waals bond;
•	n; H-bonding Molecular orbital theory for simple molecules such	ch as diatomic
molecule etc		
	Classification of Materials	2 hours
	es of materials -Metals, Semiconductors, Composite materials, Ce	ramics, Alloys,
and Polymer	8.	
	Imperfections in solids	2 hours
-	s of crystal structure –point defects, Grain boundaries, phase boundari	es, Dislocations
Screw, Euge	and Mixed Dislocations	
	Introduction to Thermodynamics and Elementary Statistical	6 hours
	Mechanics	. 1
	second laws of thermodynamics, Thermodynamic functions, enthal	
	Introduction to Ionic Conductivity, Gibb's freeenergy, Gibb'sparac assical Statistical systems, Boltzman statistics, quantum statistical s	
	se-Einstein Statistics and their applications.	ystems, renni-
	se Emisten statistics and then applications.	
Module 6	Phase Transformations	4 hours
	of phase transformation; homogeneous and heterogeneous nucle	
1110011011151115	or phase transformation, nonlogeneous and neterogeneous nucle	ation, spilloual

dec	ompositi	ion; order-disorder transfo	ormations; Martensit	ic transformation		
	- <u>F</u>					
Mo	dule 7	Magnetic, Optical & T	hermal properties o	f solid		5 hours
Ma	gnetic p	roperties- Different kind			erro, A	Antiferro, Ferri,
Sup	perpara;	Optical Properties-	Photoconductivity,	Opticalabsorptio	n &	transmission,
		escence, Fluorescence, F				
Co	ncept of	phonon, Thermal conduct	ivity, Specific heat, I	Exothermic & endo	othermi	c processes.
Mo	dule 8	Contemporary issues:				2 hours
				T-4-11	4	20 1
				Total Lec	ture:	30 hours
	<u>kt Book(</u>	*				
1		Kittel, Introduction to So				
2		ch and H. Löth, Solid-Stat	te Physics: An Introd	uction to Principle	s of Ma	aterial Science
		ourth edition, Springer				
	ference]		10.00			
1		ekker, Macmillan, Solid S				
2		an Vlack, Elements of ma				
3		Peter, Paula Julio, Physic	*	-		
4		ng, Chapman and Hall, In				W 7.1 0 0
5	Stepher 1998.	n Elliott & S. R. Elliott,	The Physics and Cr	emistry of Solids,	John	Wiley & Sons,
Mo	de of Ev	aluation: Continuous Ass	essment Test –I (CA'	T-I), Continuous A	Assessr	nent Test –II
		eminar / Challenging Ass	ignments / Completio	on of MOOC / QU	IZ, Fin	al Assessment
	st (FAT).		ſ			
		led by Board of Studies	13-12-2015	1		
Ap	proved b	y Academic Council	No. 40	Date	18-03	-2016

Course Code	Course Title	L	T	P	J	С
ECE5033	SYNTHESIS OF NANOMATERIALS AND THIN FILM DEPOSITION	2	0	2	4	4
Pre-requisite	Nil					
Course Objectiv	7 0 5*					
The course is air						
	m understand the fabrication of nanostructures for advanced devic and train the students about nanomaterial synthesis and thin file es.		epo	osit	ior	1
Expected Cours	e Outcomes::					
-	course students will be able to					
synthesis		non	nate	eria	.1	
	nd and apply vacuum technology for nanomaterial synthesis.					
	rious deposition techniques at the atomic and molecular level. knowledge about structure and properties of thin films.					
	advanced concepts in various vapour deposition techniques.					
	e and deposit nanomaterials by various methods.					
J	1 7					
	nomaterial Synthesis - Top-Down Approach			10U		
-	s- Inert gas condensation, aerosol method, Arc discharge, RF-plasr				a a	rc
technique, laser	ablation, Gas-phase synthesis, Spray Pyrolysis, Ball Milling, Comb	ust	ion			
Module 2 Na	nomaterial Synthesis - Bottom-up approach		61	100	ire	
	ods - Zero dimensional, one dimensional and two dimensional	nar				es
Nucleation theor Solvothermal/Hy	y, Homogeneous and heterogeneous nucleation, Metal nanocrysta adrothermal synthesis, Photochemical synthesis, Electrochem outes, Sonochemical routes, Hybrid methods, Sol- gel,	ls b ical	y ro	edu synt	cti the	on,
Module 3 Va	cuum technology		31	100	ire	
	rent vacuum pumps - rotary, diffusion, Turbo molecular pump, Cu	vo				np.
	ump; Concept of different gauges - pirani, penning, Pressure control			-•]		p ,
11-suonnation p	ump, concept of unceent gauges phani, penning, i ressure control	л.				
-		JI.	31	100	Irs	
Module 4 Wa	fer Growth and Epitaxial Deposition - CZ, Float zone technique; Basic Properties of different					e.g.
Module 4 Wa Crystal Growth semiconductor, g	fer Growth and Epitaxial Deposition - CZ, Float zone technique; Basic Properties of different glass); Wafer cutting; Sources and related effects of various contained effects of various conta	sub	stra	tes	(6	
Module 4 Wa Crystal Growth semiconductor, g	fer Growth and Epitaxial Deposition - CZ, Float zone technique; Basic Properties of different	sub	stra	tes	(6	
Module 4WaCrystal Growth semiconductor, § processing; EpitaModule 5Str	fer Growth and Epitaxial Deposition - CZ, Float zone technique; Basic Properties of different s glass); Wafer cutting; Sources and related effects of various contar axial growth- Growth kinetics of epitaxy, Doping, Growth modes. ucture and properties of thin films	subs nina	stra atio 4 l	ites n; ` nou	(e Wa	fer
Module 4WaCrystal Growth semiconductor, g processing; EpitaModule 5StrDefinition of thi parameters and	fer Growth and Epitaxial Deposition - CZ, Float zone technique; Basic Properties of different splass); Wafer cutting; Sources and related effects of various contartaxial growth- Growth kinetics of epitaxy, Doping, Growth modes. ucture and properties of thin films n films- Environment (Gas phase and plasma) for thin film deposit their effects on film growth; Physical parameters for evaluation	subs nina	stra atio 4 1	n; ' n; ' nou	(e Wa u rs osit	fer
Module 4WaCrystalGrowthsemiconductor, gprocessing; EpitaModule 5StrDefinition of thiparameters andSurface roughne	fer Growth and Epitaxial Deposition - CZ, Float zone technique; Basic Properties of different glass); Wafer cutting; Sources and related effects of various contant axial growth- Growth kinetics of epitaxy, Doping, Growth modes. ucture and properties of thin films n films- Environment (Gas phase and plasma) for thin film deposit	subs nina	stra atio 4 1 , D th	n; ' n; ' nou	(e Wa urs osit film	fer

Evaporation- Thermal evaporation, resistance evaporation, Electron beam evaporation, Ion vapor evaporation and Cathodic arc deposition; Molecular Beam Epitaxy; Sputtering- Glow discharge sputtering, Magnetron sputtering, Ion beam sputtering; Atomic layer deposition (ALD)-Importance of ALD technique.

Module 7 Chemical vapor deposition techniques

4 hours

Fundamentals, Advantages and limitations of Chemical vapor deposition (CVD) techniques; Different kinds of CVD techniques- Metallorganic (MO) CVD, Photoassisted CVD, Thermally activated CVD, Plasma enhanced (RF, µ-Wave) CVD, Low pressure (LP) CVD, Atmospheric pressure (AP) CVD etc,.

Module 8 Contemporary issues:

2 hours

Advanced Topics

Total Lecture:

30 hours

Tey	xt Book(s)					
1.	Guozhong Cao. Ed Nanostructures and Nanomaterials: Synthesis, F	Properties, and				
	Applications, World Scientific Series in Nanoscience and Nanotechnology, 20	11.				
2.	G.A. Ozin and A.C. Arsenault, Nanochemistry: A chemical approach to nanor	naterials, Royal				
	Society of Chemistry, 2009.					
Ref	ference Books					
1.	Bharat Bhushan, Handbook of Nanotechnology, Springer, 2005					
2.	Hari Singh Nalwa, Handbook Of Nanostructured Biomaterials And Their Applications In					
	Nanobiotechnology, Journal of Nanoscience and Nanotechnology, 2005.					
3.	D.M. Hata, Introduction to Vacuum Technology, Prentice Hall New Jersey, 20					
4.	K. Jousten, Handbook of Vacuum Technology, John Wiley and sons, Weinheim	m, 2008.				
5.	S. Schmidt et.al., CFx thin films deposited by high power impulse magnet	tron sputtering:				
	synthesis and characterization Surf.Coat.Technol. 2011, 206, pp. 646-653.					
6.	J. George, Preparation of Thin Films, Marcel Dekker, Inc., New York. 2005.					
	ode of Evaluation: Continuous Assessment Test -I (CAT-I), Continuous Asse					
	AT-II), Seminar / Challenging Assignments / Completion of MOOC / QUIZ, Fi	nal Assessment				
	t (FAT).					
Ty	pical Projects					
	1. Green synthesis of nanoparticles and analysis using UV-Vis.					
	2. Kinetic analysis of growth of silver nanoparticles.					
	3. Demonstration of Electroless deposition process.					
	4. Growth of thin films by Electrodeposition technique.					
	5. Preparation and study of ferrofluids.					
	6. Hydrothermal synthesis of TiO2 nanoparticles and its optical study					
	de of Evaluation: Review I, II and III					
Lis	t of Challenging Experiments (Indicative)					
1.	Wet Chemical synthesis of Silver Quantum Dots - Effect of viscosity on the	6 hours				
	growth and its characterization by UV-Visible spectroscopy.					
2.	Synthesis of ZnO nanoparticles by wet chemical route and its optical band	6 hours				
	gap calculation.					
3.	Mie formalism of Optical absorption of Ag and Au nanoparticles for size	4 hours				
	estimation					

4.	Calculation of d-spacing and crys	stallite size of Nano	materials from X-	ray	4 hours
	diffraction data.				
5.	5. Thin film deposition using Electroplating technique and morphology				3 hours
characterization using Optical microscope.					
6.	6. Fabrication of thin films using Spin coating technique.				3 hours
7.	Fabrication of metal thin films or	silicon/glass subst	rate using Metal		4 hours
	evaporation Unit				
			Total Laboratory	Hours	30 hours
Mod	de of Evaluation: Continuous asses	sment of challengin	ng experiments /Fin	nal Asse	essment Test
(FA	T).				
Rec	ommended by Board of Studies	13-12-2015		_	
App	roved by Academic Council	No. 40	Date	18-03	-2016

Course Code	Course Title	LT	P J	С
ECE5034	NANOMATERIAL CHARACTERIZATION	3 0	20	4
	TECHNIQUES			
Pre-requisite	Nil			
Course Objecti				
The course is air				
	em understand various Nanostructure characterization techniques			
	e students on state-of-the-art metrology tools such as Scanning Pro	be		
	opes and optical spectroscopes. them to study the material's structure and properties that a	ra prol	had an	4
5. Enable measure		ie pio	bed all	a
measure	u.			
Expected Cour	se Outcomes:			
Students will be				
1. Be conve	ersant with conventional aspects of metrological tools.			
2. Be aware	e of various morphological techniques and selecting appropriate to	ols for	their	
future re	search.			
	iar with various spectroscopic techniques.			
	ted with the Scanning probe techniques for characterisation.			
	vanced optical and magnetic characterization techniques.			
	characterise and analyse the samples with suitable techniques.			
Module 1	Introduction to Metrology		nours	
	trology- Accuracy, precision and reliability; Types of Errors - Systems, Statistical analysis of errors	tematic	Errors	
and Random Eri	rors, Statistical analysis of errors.			
Module 2	Microscopy Techniques	81	nours	
	copy; Electron microscopy- Scanning Electron Microscopy,			ζ;
	ectron Microscopy; EELS; SPM.	,		
		T		
Module 3	Spectroscopy Techniques		nours	
	roscopy; Ellipsometer; XPS; XAS; XRD; Raman Spectrosco	ру -	Surface	2 -
enhanced Rama	n Spectroscopy.			
Module 4	Scanning Tunneling Microscopy	81	ours	
	f Scanning Probe Microscopes; Scanning Tunneling Microscope			of
	tum Mechanical Tunneling phenomenon in STM, Different mode			
	of operation, applications.			
Module 5	Atomic Force Microscopy	7 ł	ours	
	Microscope - Modes of operation of AFM, Advanced Modes of	f AFM	- Forc	e
Modulation, Co	nductive AFM, EFM, MFM, SCM.			
Madula	Near Field Scorning Onticel Microscory	51		
Module 6	Near Field Scanning Optical Microscopy		nours	
r meipies of op	eration, Different modes of operation, Spectroscopic Applications	01 1130	JIVI.	
Module 7	Magnetic Characterization	21	ours	
			10013	
	ponents of SQUID systems, Vibrating Sample Magnetometer (VS	M)		

Moo	lule 8 Contemporary issues:	2 hours
Adv	anced Topics	
T	Total	45 Hours
	t Book(s)	ation. A dreamage
1.	R.W. Cahn, E.M. Lifshitz, Concise Encyclopedia of Materials Characterize	ation: Advances
2.	in Materials Sciences and Engineering, Elsevier, 2016. Yang Leng, Materials Characterization: Introduction to Microscopic and	d Spectroscopic
۷.	Methods, John Wiley & Sons, 2013.	a specifoscopic
Refe	erence Books	
1	Richard Leach, Fundamental Principles of Engineering Nanometrology, Els	evier. 2014.
2	Mauro Sardela, Practical Materials Characterization, Springer, 2014.	
3	Ewen Smith, Geoffrey Dent, Modern Raman Spectroscopy: A Practical Wiley & Sons, 2013.	Approach, John
4	Nikodem Tomczak, Kuan Eng Johnson Goh, Scanning Probe Micr Scientific, 2011.	oscopy, World
5	Ernst Meyer, Hans J. Hug, Roland Bennewitz, Scanning Probe Microscop Tip,Springer Science & Business Media, 2013.	
6	Vladimir V. Tsukruk, Srikanth Singamaneni, Scanning Probe Microscopy Fundamentals and Practices, John Wiley & Sons, 2012.	of Soft Matter:
7	H. Weinstock, SQUID Sensors: Fundamentals, Fabrication and Applica Science & Business Media, 2012.	ations, Springer
8	Sam Zhang, Lin Li, Ashok Kumar, Materials Characterization Techniques, 2008.	CRC Press,
Mod	le of Evaluation: Continuous Assessment Test –I (CAT-I), Continuous Asses	sment Test –II
	T-II), Seminar / Challenging Assignments / Completion of MOOC / QUIZ, F	
Asse	essment Test (FAT).	
	of challenging Experiments (Indicative)	
1.	STS analysis of CNT.	4 hours
2.	Analysis of magnetic nanoparticle with MFM	4 hours
3.	Application of Electrostatic Force Microscopy.	3 hours
4.	Characterization of Graphene with optical microscope.	4 hours
5.	Measure the blood glucose with electrochemical workstation	3 hours
6.	Study the band gap of semiconductor nanoparticle using UV-Vis spectroscopy	3 hours
7.	Measure the band gap and structure of crystal with XRD.	3 hours
8.	Elemental analysis using EDAX	3 hours
9.	Study the property of graphene using Raman Spectroscopy.	3 hours
	Total Laboratory Hours	30 hours
Moc (FA	le of Evaluation: Continuous assessment of challenging experiments /Final As Γ).	ssessment Test
Rec	DescriptionDescriptionDescription13-12-2015	
App	roved by Academic Council No. 40 Date 18-	03-2016

Recommended by Board of Studies	13-12-2015		
Approved by Academic Council	No. 40	Date	18-03-2016

Course Code	Course Title	L T P J C
ECE6032	NANOELECTRONICS	2 0 2 4 4
Pre-requisite	ECE5031- Quantum Physics for Nanostructures	
Course Object	ives:	
The course is a		
1. Make th	em understand various advanced concepts in nanoelectronics.	
2. Explore	the fundamentals on QED, SED, Molecular electronics and spintronics.	
-	e students on state-of-the-art computational tools for modelling and simu	ulation of
	ctronics devices.	
Expected Cou	rse Outcomes:	
Student will be		
1. Gain the	concepts of nanoelectronics such as ballistic transport and quantum con-	finement.
	and various nanostructures and its applications towards Quantum Electro	
	the fundamentals of Molecular Electronics	
	he knowledge of Single Electron Devices and carbon based nanoelectron	nic devices.
	ne fundamentals of Spintronics.	
6. Design	and simulate various advanced nanoelectronic devices.	
Module 1	Introduction to Nanoelectronics	3 hours
Limitations o	f the conventional MOSFETs at Nanoscales, MOSFET Scalir	ng & implications,
Introductory d	oncepts of Ballistic transport and Quantum confinement, Difference	0 1
	log version) and Single Electron Devices (as digital version) of Nanoele	
× ×		
Module 2	Nanostructures and Quantum Electronic Devices	4 hours
	al structures- Quantum wells, Quantum wires and Quantum dots; Densi	
dimensional st		-
Transistor; Res	onant tunneling phenomena and its applications in diodes and transistors	
Module 3	Molecular Electronics	3 hours
	sics; Fabrication of molecular electronics-based transistor devices; Cond	
	luction mechanism in organic polymers; Polymer Electronics; Self-Asse	
1 2		
Module 4	Single Electron Devices	5 hours
	eration- Single-Electron Effect, Coulomb Blockade Phenomenon; Th	
1 1	- Energy of Quantum Dot system, Single-Electron Quantum-Dot	-
	inductance Oscillation and Potential Fluctuation; Transport under Finit	
	ulomb Blockade Devices.	
Module 5	Carbon Nanoelectronics	4 hours
	bes - SWCNTs and MWCNTs; 1D quantization in nanotubes- van	
	CNTs; CNT FETs- Device characteristics, CNT-TUBFET, CNT-SI	0
	ic structure of graphene; Graphene FETs- GNRFETs.	, and rano () iii
. –, –	e surveyore of Stuphene, Stuphene (11) State 115.	

Module 6 Spintronics

2 hours

Fundamentals	of spintronics; Spintronic d	evices- spin diodes an	d spin transistors	
		<u> </u>		
Module 7	Current Nanoelectronic			7 hours
Multi-gate M		cally Induced Junctio	ed SOI-MOSFET, Double-Cons for EJ-MOSFETs, Balli	
Module 8	Contemporary issues:			2 hours
			Total Lecture Hours	30 hours
Text Book(s)				
	da, David Ferry, Nanaosca	le Silicon Devices, CR	RC Press, Taylor & Francis C	Group, 2015.
	, P. Glosekotter, Nanoelect			1 '
Reference Bo	oks			
1. Suprio I	Patta, Lessons from nanoele	ctronics, World Scient	tific publisher, 2015.	
2. Karl Go	ser, Peter Glosekotter, Jan D	Dienstuhl, Nanoelectro	onics and Nanosystems- From	m Transistors
	ular and Quantum Devices,			
	Rao and A. Govindaraj, Nan			
	-	tron Devices and their	r Applications, IEEE proceed	dings, vol. 87,
	oril 1999.p 606- 632.			
	d M. J. Thornton Spin Elect		0	• • • •
			tor, Cambridge University p	
			Continuous Assessment Tes	. , .
		ipletion of MOOC / C	UIZ, Final Assessment Test	. (FAI).
Typical Proj 1. Design		ith 10nm 16nm abon	nel dimensions by referring	a latast journal
-	-		n and electrical characteristic	•
	ess and device simulators.	through band diagram	in and cleethear characteristic	es by make use
-		16nm technology no	de by referring a latest jou	rnal paper and
-			rical characteristics by make	
-	vice simulators.	6	5	I
3. Design	a gate around FINFET v	with 5nm fin length	and 16nm channel length	dimensions by
referrin	ng a latest journal paper an	d analyze its perform	nance through band diagram	and electrical
	eristics by make use of proc			
	-	-	ucture and DOS of various ty	-
	-	ations and plot band	structure and DOS of va	rious types of
01	ne nano ribbons(GNRs).			• • • •
	eristics.	im transport of a 2L	D graphne FET and analyz	e its electrical
Mode of Evalu	ation: Review I, II and III			
Recommended	by Board of Studies	13-12-2015		
	Academic Council	No. 40	Date 18-0	3-2016

Course Code	Course Title	L T P J C
ECE6033	NANOPHOTONICS	3 0 0 0 3
Pre-requisite	ECE5031 - Quantum Physics for nanostructures	
Course Objective The course is ain		
		volved in suc
1. Expose devices.	them to the emerging area of nanophotonics and the phenomena inv	volved ill suc.
	deep understandings of light – matter interaction at nanoscale.	
	fferent types of nanophotonic crystal based devices and systems.	
<i>c:</i>		
Expected Cours	e Outcomes:	
	urse student will be able to	
	foundations of nanophotonics.	
	nd the mathematical synthesis of Maxwell equations for Photonic sy	stems.
	he understanding and importance of confinement and propagation.	
	e knowledge of 1-D, 2-D and 3-D Photonic Crystals. design and scope of nano-photonics applications.	
	foundation of plasmonics.	
Module 1 Fou	indations of Photonics	4 hours
Photons and Ele	ectrons - Similarities and differences, Light Interaction with Ma	tter, Complex
	and dielectric constant, Dispersion in Materials.	1
	xwell equations for Photonic systems	6 hours
	equations and their interpretations, Master's Equation for dielectric	medium and
its analytical solu	111011.	
Module 3 Cor	nfinement and Propagation	6 hours
	Photons and Electrons, Co-operative effects for Photons ar	
	ugh Classically Forbidden Zone- Tunneling, Concept of Near-Fiel	
10	tals and Evanescent wave.	1
		I
	otonic Crystals	8 hours
	D Photonic crystal, Theoretical and mathematical description of P	hotonic band
gap, Features and	d fabrication of Photonic crystals.	
Module 5 Ap	olications of Photonics	6 hours
1.1	ptical fiber, filters, switching devices, Kerr effect devices; Super Le	
	s, Prisms and Meta-materials, Graphene photonics.	
Module 6 Pho	sphor materials in Photonics	7 hours
	nosphorescence, rare earth doped nanostructures, activator and sen	sitizer, energ
transfer process,	life time, down and up conversation, FRET.	
	•	
	smonics	6 hours
runuamentais, v	wave equations, surface plasmon-polaritons, Plasmonics in go	iu and silve

Mo	dule 8	Contemporary issues:			2 hours
				Total Lecture	: 45 hours
Тех	t Book((s)			
1.		Prasad, Nanophotonics, Wiley-	Interscience, 2004.		
2.		D. Joannopoulos, Steven G. J ls: Molding the Flow of Light,	,	,	,
Ref	erence 1	Books		•	
1.		hi Ohtsu, Kiyoshi Kobayash les of Nanophotonics, CRC Pi			Iakoto Naruse,
2.	Stefan	A. Maier, Plasmonics: Fundar	nentals and Applicat	ions, Springer Scienc	e, 2007.
3.		Lakowicz, Principle of Fluore ner, Newyork, 2007	escence Spectroscop	y, third Edition, Klu	wer Academic
Mo		valuation: Continuous Assessm	ent Test –I (CAT-I)	, Continuous Assessi	nent Test –II
(CA	AT-II), S	eminar / Challenging Assignm	nents / Completion o	f MOOC / QUIZ, Fin	al Assessment
Tes	t (FAT).				
Rec	ommen	ded by Board of Studies	13-12-2015		
App	proved b	y Academic Council	No. 40	Date 1	8-03-2016

Programme Electives

Course Cod	e Course Title	LT	P	J	С
ECE5035		2 0			3
	TECHNOLOGY				
Pre-requisit	e Nil				
Course Obje					
The course is					
	them understand the physics of semiconductor materials and devices.				
	the the working mechanism and design of optoelectronic devices.				
3. Train	them to solve bandgap models and design different semiconductor devic	es.			
Expected Co	ourse Outcomes:				
Students will					
1. Gain i	n-depth knowledge in semiconductor physics				
	re knowledge of mathematical model of various device fabrication proce	esse	3		
	n-depth knowledge of formation and properties of PN junctions				
	n the fundamentals of metal-semiconductor junctions				
	he physics of optoelectronic devices				
	stand the fabrication and characteristics of nanoscale MOSFETs	onia	n 1,	ori	0110
11 2	the concepts and techniques to solve bandgap model equations and d onductor devices.	esig	II V	an	Jus
senne	onductor devices.				
Module 1	Semiconductor Physics	6	6 ha	our	S
Energy Band	s and Carrier Concentration in thermal Equilibrium: Semiconductor Ma	teri	als,	Bε	isic
Crystal Struc	cture, Basic Crystal Growth Technique, Valence Bands, Energy Bas	nds,	In	trin	isic
	entration, Donors and Acceptors. Carrier Transport Phenomena: Carrier				
	eneration and Recombination Processes, Continuity Equation, Thermio	nic	Em	iss	ion
Process, Tuni	neling Process, High-Field Effects.				
Module 2	Device Process stages I		B ho		
	ess stages I: Mathematical models relevant to thermal diffusion and ion				
	ng. Pattern transfer; Optical lithography, Photoresists, Alignment a	-			
Etching.	-8		···r		,
Module 3	Device Process stages II	3	6 ho	our	S
Mathematica	l models relevant to Deposition; Physical and chemical vapor deposition	, Ep	itay	кy.	
Process Integ	ration: Device isolation, contacts metallization.				
			- 1		
	P-N Junction		5 hc		
	ation, Device physics: Thermal equilibrium, Internal electro-stations of the state				
-	, reverse bias, Diode equation. Capacitive effect: Junction and diffusion				
	transient analysis of Diodes.	up	uel	ull	
,	٠ •				
Module 5	Metal-Semiconductor Contacts and Schottky Diodes	4	h ha	our	S

Metal-Semiconductor Junction diode Fabrication, Device Physics: Ideal MS contacts, Schottky diode-Electrostatics, I-V characteristics, DC, AC and transient analysis. Metal-Semiconductor contacts: Ohmic contacts, Schottky contacts, Tunnel contacts and Annealed and alloyed contacts.

Module 6 Optoelectronic Diodes

Photodiode Fabrication, device Physics of pn Junction Photodiodes, p-i-n Photo diodes. Principle of operation and fabrication technologies of Solar cell, LED and LASER diodes.

Module 7 MOSFET

MOS capacitor, MOSFET device fabrication, MOSFET Physics: I-V characteristics, Subthreshold region, Body effect, Capacitive effect, small and large signal model. MOSFET Short Channel effects: Punch through, DIBL, Hot electron effect, Velocity Saturation, Leakage current. MESFETs and MODFET analysis.

Module 8	Contemporary issues:	2 hours
Advanced 7	opics	
	Total Lecture:	30 Hours

Text Books(s)

- 1. S. M. Sze and Ming-Kwei Lee, Semiconductor Devices Physics and technology, John Wiley & Sons, 2013.
- 2. Grundmann and Marius, Physics of Semiconductors, Springer, 2010

Reference Books

- 1. Ben G. Streetman and Sanjay Banerjee, Solid State Electronic Devices, Pearson Ed, 2014.
- 2. M. S. Tyagi, Introduction to semiconductor materials and devices, John Wiley & Sons, 2008.
- 3. Campbell, Stephan, Fabrication Engineering at the Micro and Nanoscale, Oxford University Press, 2008.
- 4. Robert F. Pierret, Semiconductor Device Fundamentals, Pearson Education, 2006.
- 5. Richard C. Jaeger, Introduction to Microelectronic Fabrication, Prentice Hall, 2001.

Mode of Evaluation: Flipped Class Room, [Lecture to be videotaped], Use of physical and computer models to lecture, Visit to Industry, Min of 2 lectures by industry experts

- Typical Projects

 1. Solve relevant mathematical equations and plot band structure then extract effective mass of direct and indirect bandgap semiconductors.

 2. Solve drift-diffusion equation for transport parameters (Drift velocity, mobility and
 - 2. Solve drift-diffusion equation for transport parameters (Drift velocity, mobility and conductivity) of direct and indirect band gap materials.
 - 3. Design a P-N junction diode with smallest dimensions by referring a latest journal paper and analyze its performance through band diagram and electrical characteristics.
 - 4. Design a MOSFET with smallest dimensions by referring a latest journal paper and analyze its performance through band diagram and electrical characteristics by make use of process and device simulators.
 - 5. Design a MOSFET with smallest dimensions by referring a latest journal paper and analyze its performance through band diagram and electrical characteristics by make use of process and device simulators.
 - 6. Design a LASER diode with smallest dimensions by referring a latest journal paper and analyze its performance through band diagram and electrical characteristics by make use of process and device simulators.

Mode of Evaluation: Review I, II and III

4 hours

3 hours

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F('F5A?4	Course Title MEMS To NEMS	L T P J 2 0 0 4
ECE5036	None None	2 0 0 4
Pre-requisite	INOILE	
Course Objectiv	7AC•	
The course is air		
	m to understand the technology of MEMS and NEMS.	
	hem about fabrication processes for development of MEMS/NEM	IS devices a
systems.	nen ubbut fubrication processes for acverophicit of MEMIS/1424.	
	about the potential applications of NEMS.	
<u>J.</u> <u>2</u>		
Expected Cours	e Outcomes:	
	urse students will be able to	
1. Acquire	he knowledge of mechanisms in MESM/NEMS	
2. Understa	nd various engineering mechanics of microsystems	
3. Gain the	concept in finite element analysis of microsystems	
4. Obtain th	e knowledge of MEMS fabrication	
	knowledge of quantum effects in MEMS/NEMS	
	e knowledge of system integration in MEMS/NEMS	
7. Design at	nd simulate micro/nano sensors and actuators.	
		Г
Module 1 Int	roduction EMS / NEMS and various devices, Scaling geometry, Rigid Bo	2 hours
· · · · · · · · · · · · · · · · · · ·	transfer, Fluid mechanics and Heat transfer. gineering mechanics for Microsystems design	4 hours
	of Thin plates, Mechanical vibration, Resonant vibration, Des	
	and Thermal analysis, Thermal effects on Mechanical strength of N	
	ite Element Analysis	5 hours
Concept of FEA equations, Form	ite Element Analysis A, Comparison with other methods, Formulation from the governi ulation based on stationary total potential, 1-D and 2-D Finite Ele	ng Differen
Concept of FEA equations, Form Examples.	A, Comparison with other methods, Formulation from the governi ulation based on stationary total potential, 1-D and 2-D Finite Ele	ng Differen ment Analy
Concept of FEA equations, Form Examples.	A, Comparison with other methods, Formulation from the governi ulation based on stationary total potential, 1-D and 2-D Finite Ele erview of Micro - Scale fabrication	ng Different ment Analy 2 hours
Concept of FEA equations, Form Examples. Module 4 Ove Microsystem fa	A, Comparison with other methods, Formulation from the governi ulation based on stationary total potential, 1-D and 2-D Finite Ele	ng Different ment Analy 2 hours
Concept of FEA equations, Form Examples. Module 4 Ove Microsystem fa PVD,CVD,LIGA	A, Comparison with other methods, Formulation from the governi ulation based on stationary total potential, 1-D and 2-D Finite Ele erview of Micro - Scale fabrication brication process-Lithography, Dry and wet etching, Thin fil	ng Different ment Analy 2 hours
Concept of FEA equations, Form Examples. Module 4 Ove Microsystem fa PVD,CVD,LIGA	A, Comparison with other methods, Formulation from the governi ulation based on stationary total potential, 1-D and 2-D Finite Ele erview of Micro - Scale fabrication brication process-Lithography, Dry and wet etching, Thin fil A, Micromolding, Electro-deposition	ng Different ment Analy 2 hours Im depositie
Concept of FEA equations, Form Examples. Module 4 Ove Microsystem fa PVD,CVD,LIGA Module 5 Que Casimir Force a experimental tec	A, Comparison with other methods, Formulation from the governi ulation based on stationary total potential, 1-D and 2-D Finite Ele erview of Micro - Scale fabrication brication process-Lithography, Dry and wet etching, Thin fil A, Micromolding, Electro-deposition	ng Different ment Analy 2 hours Im depositi 6 hours Nanotribolo
Concept of FEA equations, Form Examples. Module 4 Over Microsystem fa PVD,CVD,LIGA Module 5 Que Casimir Force a experimental tec frictional anisotr	A, Comparison with other methods, Formulation from the governi ulation based on stationary total potential, 1-D and 2-D Finite Ele erview of Micro - Scale fabrication brication process-Lithography, Dry and wet etching, Thin fil A, Micromolding, Electro-deposition antum effects and its influence in MEMS and NEMS, control of casimir force, Thin hniques for studying anotribology, phonic friction, electronic friction opy, stick-slip dynamics	ng Different ment Analy 2 hours Im depositi 6 hours Nanotribolo
Concept of FEA equations, Form Examples. Module 4 Ove Microsystem fa PVD,CVD,LIGA Module 5 Qu Casimir Force a experimental tec frictional anisotr Module 6 NE	A, Comparison with other methods, Formulation from the governi ulation based on stationary total potential, 1-D and 2-D Finite Ele erview of Micro - Scale fabrication brication process-Lithography, Dry and wet etching, Thin fil A, Micromolding, Electro-deposition antum effects and its influence in MEMS and NEMS, control of casimir force, Thin hniques for studying anotribology, phonic friction, electronic friction opy, stick-slip dynamics	ng Different ment Analy 2 hours Im deposition 6 hours Nanotribolo , static friction 7 hours

Mo	dule 7	System Integration				2 hours
Sys	stem Inte	gration and reliability				
Mo	dule 8	Contemporary issues:				2 hours
Ad	vanced T	lonios				
Au	vanceu 1	opics				
				Total Leo	cture:	30 hours
	xt Books					
1.	Tai-ran TMGH	Hsu, MEMS and microsyster 2008	ems design a	nd manufacture, Na	noscale	Engineering,
2.		Edward Lyshevski, MEMS and	NEMS: Syste	ms, Devices, and Stru	uctures,	CRC, 2002
Ref	ference		¥	, ,	·	·
1.	P.Sesh	a, Text Book of Finite Element	Analysis, PHI,	2006		
2.		Edward Lyshevski, Nano- and			CRC, Pi	ress, 2000
3.		n Bhushan, Handbook of Micro				
4.		us T. Leondes, MEMS/NEMS		<u> </u>		
		aluation: Continuous Assessme	· · ·	<i>, , ,</i>		
		eminar / Challenging Assignme	nts / Completio	on of MOOC / QUIZ	, Final A	Assessment
	t (FAT).					
Iy	pical Pro	•				
		gn of capacitance based actuate				
		ly of scaling effects in a magnet ulation of peizo based cantileve				
		ecular dynamics simulation	l Deallis			
		elerometer design				
		ign of capacitance based actuate	ors.			
Mo	de of Ev	aluation: Review I, II and III				
Rec	commen	led by Board of Studies	13-12-2015			
Ap	proved b	y Academic Council	No. 40	Date 1	8-03-20)16

Course Code	Course Title	
ECE5037	NANOSENSORS	3 0 0 0 3
Pre-requisite	Nil	
Course Objectiv		
The course is air		
	overview of basic nanosensor technology with examples drawn	from existing
1	and literatures.	
	hem to identify suitable nanosensors and nanodevices for vari	ious potential
application		
3. Make the	m acquainted with various types of nanosensors and its potential ap	plications.
-		
Expected Cours		
	s course students will be able to	
•	and understand various micro and nano-sensors and their working.	
	terial's properties used for the fabrication of nanosensors.	
	fundamentals of packaging and characterization of nanosensors.	
	various types of mechanical, chemical and optical nano-sensing sys	stems.
5. Use nano	structured materials for developing nanobiosensors.	
Module 1 Mid	cro and nano-sensors	3 hours
Songing principle	as sensor types and classification. Machanical acoustic magnetic	thormal
	es, sensor types and classification – Mechanical, acoustic, magnetic,	
chemical, radiati	es, sensor types and classification – Mechanical, acoustic, magnetic, on; microsensors; sensors based on surface - acoustic wave devices,	
chemical, radiati microfluids	on; microsensors; sensors based on surface - acoustic wave devices,	, biosensor,
chemical, radiati microfluids Module 2 Ma	on; microsensors; sensors based on surface - acoustic wave devices, terials for Nanosensors	, biosensor, 8 hours
chemical, radiati microfluids Module 2 Ma Shape and size	on; microsensors; sensors based on surface - acoustic wave devices, terials for Nanosensors Dependence of Properties at Nanoscale, Surface Energy of a Solid	, biosensor, 8 hours , Core/Shell-
chemical, radiati microfluids Module 2 Ma Shape and size Structured Nano	on; microsensors; sensors based on surface - acoustic wave devices, terials for Nanosensors Dependence of Properties at Nanoscale, Surface Energy of a Solid oparticles, Metallic Nanoparticles and Plasmons Optical Propert	, biosensor, 8 hours , Core/Shell- ties of Bulk
chemical, radiati microfluids Module 2 Ma Shape and size Structured Nano Metals and Met	on; microsensors; sensors based on surface - acoustic wave devices, terials for Nanosensors Dependence of Properties at Nanoscale, Surface Energy of a Solid oparticles, Metallic Nanoparticles and Plasmons Optical Propert allic Nanoparticles, Quantum Dots, Carbon Nanotubes, Inorganic	, biosensor, 8 hours , Core/Shell- ties of Bulk
chemical, radiati microfluids Module 2 Ma Shape and size Structured Nano	on; microsensors; sensors based on surface - acoustic wave devices, terials for Nanosensors Dependence of Properties at Nanoscale, Surface Energy of a Solid oparticles, Metallic Nanoparticles and Plasmons Optical Propert allic Nanoparticles, Quantum Dots, Carbon Nanotubes, Inorganic	, biosensor, 8 hours , Core/Shell- ties of Bulk
chemical, radiati microfluids Module 2 Ma Shape and size Structured Nano Metals and Met Nanoporous Mat	on; microsensors; sensors based on surface - acoustic wave devices, terials for Nanosensors Dependence of Properties at Nanoscale, Surface Energy of a Solid oparticles, Metallic Nanoparticles and Plasmons Optical Propert allic Nanoparticles, Quantum Dots, Carbon Nanotubes, Inorganic erials.	, biosensor, 8 hours , Core/Shell- ties of Bulk c Nanowires,
chemical, radiati microfluids Module 2 Ma Shape and size Structured Nano Metals and Met Nanoporous Mat Module 3 Pac	on; microsensors; sensors based on surface - acoustic wave devices, terials for Nanosensors Dependence of Properties at Nanoscale, Surface Energy of a Solid oparticles, Metallic Nanoparticles and Plasmons Optical Propert allic Nanoparticles, Quantum Dots, Carbon Nanotubes, Inorganic erials. kaging and characterization of sensors	, biosensor, 8 hours , Core/Shell- ties of Bulk 2 Nanowires, 4 hours
chemical, radiati microfluids Module 2 Ma Shape and size Structured Nano Metals and Met Nanoporous Mat Module 3 Pac Design, fabricat	on; microsensors; sensors based on surface - acoustic wave devices, terials for Nanosensors Dependence of Properties at Nanoscale, Surface Energy of a Solid oparticles, Metallic Nanoparticles and Plasmons Optical Propert allic Nanoparticles, Quantum Dots, Carbon Nanotubes, Inorganic erials.	, biosensor, 8 hours , Core/Shell- ties of Bulk 2 Nanowires, 4 hours
chemical, radiati microfluids Module 2 Ma Shape and size Structured Nano Metals and Met Nanoporous Mat Module 3 Pac Design, fabricat	on; microsensors; sensors based on surface - acoustic wave devices, terials for Nanosensors Dependence of Properties at Nanoscale, Surface Energy of a Solid oparticles, Metallic Nanoparticles and Plasmons Optical Propert allic Nanoparticles, Quantum Dots, Carbon Nanotubes, Inorganic erials. kaging and characterization of sensors	, biosensor, 8 hours , Core/Shell- ties of Bulk 2 Nanowires, 4 hours
chemical, radiati microfluids Module 2 Ma Shape and size Structured Nano Metals and Met Nanoporous Mat Module 3 Pac Design, fabricati level.	on; microsensors; sensors based on surface - acoustic wave devices, terials for Nanosensors Dependence of Properties at Nanoscale, Surface Energy of a Solid oparticles, Metallic Nanoparticles and Plasmons Optical Propert allic Nanoparticles, Quantum Dots, Carbon Nanotubes, Inorganic erials. kaging and characterization of sensors	, biosensor, 8 hours , Core/Shell- ties of Bulk 2 Nanowires, 4 hours
chemical, radiati microfluids Module 2 Ma Shape and size Structured Nano Metals and Met Nanoporous Mat Module 3 Pac Design, fabricat level. Module 4 Me	on; microsensors; sensors based on surface - acoustic wave devices, terials for Nanosensors Dependence of Properties at Nanoscale, Surface Energy of a Solid oparticles, Metallic Nanoparticles and Plasmons Optical Propert allic Nanoparticles, Quantum Dots, Carbon Nanotubes, Inorganic erials. kaging and characterization of sensors ion and characterization, Method of packaging at dye level, zero lev chanical Nanosensors	, biosensor, 8 hours , Core/Shell- ties of Bulk 2 Nanowires, 4 hours rel and first 8 hours
chemical, radiati microfluids Module 2 Ma Shape and size Structured Nance Metals and Met Nanoporous Mate Module 3 Pace Design, fabricate level. Module 4 Me Mass sensing-	on; microsensors; sensors based on surface - acoustic wave devices, terials for Nanosensors Dependence of Properties at Nanoscale, Surface Energy of a Solid oparticles, Metallic Nanoparticles and Plasmons Optical Propert allic Nanoparticles, Quantum Dots, Carbon Nanotubes, Inorganic erials. kaging and characterization of sensors ion and characterization, Method of packaging at dye level, zero lev chanical Nanosensors Nanogram Mass Sensing by Quartz Crystal Microbalance, I	, biosensor, 8 hours , Core/Shell- ties of Bulk 2 Nanowires, 4 hours rel and first 8 hours MEMS/NEMS
chemical, radiati microfluids Module 2 Ma Shape and size Structured Nano Metals and Met Nanoporous Mat Module 3 Pac Design, fabricat: level. Module 4 Me Mass sensing- Resonators; Dis	on; microsensors; sensors based on surface - acoustic wave devices, terials for Nanosensors Dependence of Properties at Nanoscale, Surface Energy of a Solid oparticles, Metallic Nanoparticles and Plasmons Optical Propert allic Nanoparticles, Quantum Dots, Carbon Nanotubes, Inorganic erials. kaging and characterization of sensors ion and characterization, Method of packaging at dye level, zero lev chanical Nanosensors	, biosensor, 8 hours , Core/Shell- ties of Bulk c Nanowires, 4 hours rel and first 8 hours MEMS/NEMS sor, Coulomb
chemical, radiati microfluids Module 2 Ma Shape and size Structured Nano Metals and Met Nanoporous Mat Module 3 Pac Design, fabricat level. Module 4 Me Mass sensing- Resonators; Dis Blockade Electro	on; microsensors; sensors based on surface - acoustic wave devices, terials for Nanosensors Dependence of Properties at Nanoscale, Surface Energy of a Solid oparticles, Metallic Nanoparticles and Plasmons Optical Propert allic Nanoparticles, Quantum Dots, Carbon Nanotubes, Inorganic erials. kaging and characterization of sensors ion and characterization, Method of packaging at dye level, zero lev chanical Nanosensors Nanogram Mass Sensing by Quartz Crystal Microbalance, I placement sensor- Electron Tunneling Displacement Nanosens ometer-Based Displacement Nanosensor, Nanometer-Scale Displace	, biosensor, 8 hours , Core/Shell- ties of Bulk 2 Nanowires, 4 hours rel and first 8 hours MEMS/NEMS sor, Coulomb ement Sensing
chemical, radiati microfluids Module 2 Ma Shape and size Structured Nano Metals and Met Nanoporous Mat Module 3 Pac Design, fabricat: level. Module 4 Me Mass sensing- Resonators; Dis Blockade Electro by Single-Electro	on; microsensors; sensors based on surface - acoustic wave devices, terials for Nanosensors Dependence of Properties at Nanoscale, Surface Energy of a Solid oparticles, Metallic Nanoparticles and Plasmons Optical Propert allic Nanoparticles, Quantum Dots, Carbon Nanotubes, Inorganic erials. Kaging and characterization of sensors ton and characterization, Method of packaging at dye level, zero lev chanical Nanosensors Nanogram Mass Sensing by Quartz Crystal Microbalance, I placement sensor- Electron Tunneling Displacement Nanosensor ometer-Based Displacement Nanosensor, Nanometer-Scale Displace on Transistor, Magnetomotive Displacement Nanosensor, Piez	, biosensor, 8 hours , Core/Shell- ties of Bulk 2 Nanowires, 4 hours rel and first 8 hours MEMS/NEMS sor, Coulomb ement Sensing oresistive and
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Module 6	Optical Nanosensors		6 hours
Noble-Meta	al Nanoparticles with LS	PR and UV-Visible Spectroscopy, Nanos	ensors Based on
		ng, Colloidal SPR Colorimetric Go	
Spectrophot	tometric Sensor, Fiber-Op	ptic Nanosensors, Nanograting-Based Optica	l Accelerometer.
Module 7	Nanobiosensors		6 hours
Nanoparticl	e-Based Electrochemical	l Biosensors, CNT-Based Electrochem	ical Biosensors,
		sensor, Quantum Dot-Based Electrochem	
		Nanobiosensors, Cantilever-Based Nanobio	osensors, Optical
Nanobiosen	sors, Biochips		
Module 8	Contemporary issues:		2 hours
Advanced T	lopics		
	1		
		Total Lecture	: 45 hours
Text Book(
1. Peter H 2003	lauptmann and Tim Pown	all, Sensors: Principles and Applications, Pr	entice Hall,
2. Vinod	Kumar Khanna, Nanosens	ors: Physical, Chemical, and Biological, CR	C, 2012
Reference	Books	•	
MULTITUTUTU			
	C. Honeychurch, Nanosen	sors for Chemical and Biological Applicatio	ns: Sensing with
1. Kevin		sors for Chemical and Biological Applicatio particles, woodhead publishing, 2014	ns: Sensing with
1. Kevin Nanotu	bes, Nanowires and Nano	particles, woodhead publishing, 2014	-
1. Kevin Nanotu	bes, Nanowires and Nano heng Lim, Nanosensors: T		-
 Kevin (Nanotu Teik-C CRC, 2 	bes, Nanowires and Nano heng Lim, Nanosensors: 7 2011	particles, woodhead publishing, 2014	are and Defense,
 Kevin (Nanotu Teik-C CRC, 2 Mode of Ev 	bes, Nanowires and Nano heng Lim, Nanosensors: 7 2011 aluation: Continuous Asse	particles, woodhead publishing, 2014 Theory and Applications in Industry, Healthc	are and Defense, sment Test –II
 Kevin (Nanotu Teik-C CRC, 2 Mode of Ev 	bes, Nanowires and Nano heng Lim, Nanosensors: 7 2011 valuation: Continuous Asse eminar / Challenging Asse	particles, woodhead publishing, 2014 Theory and Applications in Industry, Healthc essment Test –I (CAT-I), Continuous Assess	are and Defense, sment Test –II
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	7 hours
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e	Nanoribbo
	6 hours
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or	s.
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Course Code Course Title T P J C L ECE5038 **CARBON NANOMATERIALS** 3 0 0 Pre-requisite | Nil **Course Objectives:**

The course is aimed to:

- 1. Make the students understand the importance of carbon based nanostructured materials.
- 2. Study various carbon allotropes, their types, structure, properties and applications.
- 3. Emphasize other carbon based nanostructured materials such as nanocones, nanofibers, nanodiscs and nanodiamonds.

Expected Course Outcomes:

At the end of course, students will be able to:

- 1. Understand the importance of carbon based nanomaterials.
- 2. Obtain the knowledge on synthesis, characterization and application of various carbon based nanomaterials such as fullerene, carbon nanotubes and graphene.
- 3. Understand the functionalization and applications of CNT & Graphene.
- 4. Gain knowledge in other carbon based nanomaterials such as nanocones, nanofibers, nanodiscs and nanodiamonds.

Carbon Nanomaterials Module 1

Introduction to Carbon Nanomaterials, Carbon allotropes and their bonding between carbon atoms.

Module 2 | Fullerene

Structure, Synthesis, Functionalization of fullerenes, Applications - Solar Cells, Hydrogen storage, Bio-applications.

Module 3 | Carbon nanotubes

Types ; Structure; Properties- Electrical, Optical, Mechanical, Vibrational properties; Nanotube synthesis - carbon arc discharge, Laser ablation, Chemical Vapor Deposition, High-pressure CO process, Purification techniques of carbon nanotube.

Module 4 | Functionalization and Applications of CNTs

8 hours Functionalization- Covalent, non-covalent, and biological; Applications - Energy storage: Batteries, Fuel Cells: H₂, Li storage, supercapacitors; Molecular electronics-Field emitting devices and Transistors, drug delivery, CNT based microscopy, Nanotube sensors.

Module 5 Graphene

Electronic band structure, Properties of Graphene: chemical, mechanical, electronic ermal. Synthesis of Graphene - Exfoliation, Epitaxial, CVD, Hummer Method; Graphene bbonsynthesis.

Module 6 | Functionalization and Applications of Graphene urs Functionalization- Covalent, non-covalent Application of Graphene; Application phene MOSFET - Opening a Band gap, Spintronics, Solar cells, gas sensors, supercapacito

6 hours

2 hours

8 hours

Mo	dule 7	Other Carbon based materia	ıls			6 hours	
Car	bon Nar	ocomposite, Nanocones, Nanof	ibers, Nanodis	cs and Nanodiamo	nds.		
Mo	dule 8	Contemporary issues:				2 hours	
				Total L	ecture:	45 Hours	
Tey	xt Book(s)					
1.	Peter.	J.F Harris, Carbon Nanotube dge University Press, 2011	e Science: S	ynthesis, Propertie	es and	Applications,	
2.		H. Warner, Franziska Schaffenentals and Emergent Application	,	, 5	hmatiuk,	, Graphene:	
Ref	ference 1						
1.	Zhong 2006	Lin Wang, Nanowires and Na	nobelts- Mate	rials, Properties a	nd Devie	ces, Springer,	
2.	Thomas Webbester, Carbon Nanotube preparation and properties, CRC Press, 1997						
3.		, G Dresselhaus, M S Dresselha press, 2004	us, Physical P	roperties of Carbo	n Nanotu	ibes, Imperial	
4.	Yury C	ogotsi, Volker Presser, Carbon	nanomaterials,	, CRC Press, 2014			
5.		Rao and A Govindaraj, N chnology series, 2011	anotubes and	Nanowires, RC	S Nano	oscience and	
6.	Michae	el J. O'Connell, Carbon Nanotuk group, 2006.	bes: Properties	and Applications,	CRC Ta	ylor and	
7.	Mikhail I. Katsnelson, Graphene: Carbon in two dimensions, Cambridge University Press, 2012						
8.	Publish	do Langa, Jean-Francois Nieren iing, 2007		•			
(CA		aluation: Continuous Assessme eminar / Challenging Assignme	· ·				
Rec	commen	led by Board of Studies	13-12-2015				
	meaned h	y Academic Council	No. 40	Date	18-03-2	016	

Course Code	Course Title	L T P J C
ECE5039	LITHOGRAPHIC TECHNIQUES FOR DEVICE	
	FABRICATION	3 0 0 0 3
Pre-requisite	Nil	
-		
Course Object	ives:	
The course is ai	med to:	
	conversant with conventional aspects of lithography, techniques relation	ated and their
	on aspects.	
	ce various existing Lithography techniques.	
	he principles, process steps and system components of the variou	s lithographic
techniq	ues.	
Expected Cour	urse students will be able to:	
		hniques
	the in-depth knowledge in optical and electron beam lithography tec	-
	tand the conventional aspects of lithography, techniques relation on aspects of X-ray, Ion, SPM based and soft lithography.	lied and their
	and understand the importance of plasmonics in lithography	
	otical Lithography	9 hours
	involved in the optical lithography; Types - Contact, proximity	
	ing; Resolution Enhancement techniques for projection systems; De	
	treme Ultraviolet lithography; Scanning Near Field Optical Lithograp	
innogrupity, Ex	iteme e niuviolet nilogruphy, seaming i tear i leta optical Enilogra	jiij.
Module 2 El	ectron Beam Lithography	8 hours
	e electrons with the substrate; Electron Lithography System compor	
	or scans; Electron resists and processing technique; Application of El	
Lithography.		
Module 3 X-	ray Lithography	4 hours
X-ray lithograp	hy system components, Resolution enhancement, X-ray mask const	ruction, X-ray
sources, x-ray re	esists.	
	n Lithography	3 hours
	system components; Focused Ion Beam Lithography; Maske	ed Ion Beam
Lithography; Io	n Projection Lithography.	
	anning Probe Lithography	8 hours
0	thography; Anodic Oxidation- Mechanism of Nano-oxidat	· 1
	y - Mechanism, DPN Types: Parallel DPN, Polymer DPN, Applic	ation of DPN;
Nano-shaving.		
		5 h
	ft Lithography	5 hours
Micro-contact	printing, Solvent-Assisted Micromoulding, Micromoulding i	5 hours n capillaries,
	printing, Solvent-Assisted Micromoulding, Micromoulding i	

Mo	dule 7	Plasmonic Nanolithography				6 hours				
Prin	nciple o	f Plasmonic Lithography, Pl	asmonic Masl	k, Near-field	Plasmonic	Lithography,				
Plasmonic Contact Lithography, Plasmonic direct write lithography.										
Module 8Contemporary issues:2 he										
				Total	Lecture:	45 hours				
					·					
Tey	xt Book(s)								
1.	M Feld	lman, Nanolithography: The A	Art of Fabricat	ting Nanoelect	ronic and	Nanophotonic				
	Device	s and Systems, Woodhead Publi	shing, 2014.							
2.	Stefano	Cabrini, Satoshi Kawata, Nanc	fabrication Ha	ndbook, CRC F	Press, 2012.					
Ref	ference]									
1.		W. Smith, Kazuaki Suzuki,	Microlithograp	hy: Science a	nd Techno	logy, Second				
		, CRC Press, 2007.								
2.		anall, Nanolithography and Patte								
3.		. Madou, Manufacturing Techn	niques for Mic	profabrication a	ind Nanote	chnology, 3rd				
		, Vol II, CRC Press, 2011.								
4.		Jackson, Micro and Nanomanu								
5.	-	e A. Tseng, Tip-Based Nanof	abrication: Fu	ndamentals and	d Applicati	ons, Springer				
		e & Business Media, 2011.								
6.	• •	sok T. Soh, Kathryn Wilder G		F. Quate, Scan	ning Probe	Lithography,				
Springer Science & Business Media, 2013.										
Mode of Evaluation: Continuous Assessment Test –I (CAT-I), Continuous Assessment Test –II										
(CAT-II), Seminar / Challenging Assignments / Completion of MOOC / QUIZ, Final Assessment										
	Test (FAT).									
	Recommended by Board of Studies 13-12-2015									
Ap	proved b	y Academic Council	No. 40	Date	18-03-2	2016				

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Course Title

PLASMONICS

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ECE5040 Pre-requisite Nil

Course Objectives:

The course is aimed to:

- 1. Give a clear idea of changes in optical properties of nanostructures.
- 2. Enable to understand the fundamentals about surface plasmon polariton and plasmonic waveguides.
- 3. Make acquainted with various types of Spectroscopy and sensing techniques based on plasmonics.

Expected Course Outcomes:

At the end of course students will be able to:

- 1. Acquire the knowledge on electromagnetics of metallic nanoparticles.
- 2. Understand the fundamentals of surface plasmon polariton, and LSPR.
- 3. Understand the excitation dynamics at nanoscale.
- 4. Learn about nanocomposites and its application in the field of optoelectronics.
- 5. Familiar with nanostructured molecular architectures.
- 6. Obtain the basics on Surface-Plasmon-Polariton-Based Sensors.
- 7. Apply surface plasmon polariton, and LSPR concepts for designing nanophotonic devices.

Module 1 | Electromagnetics of Metallic Nano-particles 5 hours

Metallic Nano-particles, Maxwell equation and Electromagnetic wave equation, dispersion of the free electron gas and volume plasmons, real metals and intraband transitions, Electromagentic field in metals, Local Field Enhancement, Sub-wavelength aperture plasmonics,

Module 2 Plasmonic waveguides

4 hours Elements for surface plasmon polariton propagation, surface plasmon polariton band gap structures, metal nanowires for high confinement guiding and focusing, localized modes, metal nanoparticle waveguides

Module 3 | Localized surface plasmons

- Normal modes of sub-wavelength metal particles, Mie theory, Observations of particle plasmons, coupling between localized plasmons, void plasmons and metallic nanoshells

Module 4 Nanocontrol of Excitation Dynamics 4 hours Nanostructure and excited states. Rare earth doped nanostructures Up-converting nanophores. Photon avalanche. Quantum cutting. Site isolating nanoparticles, prism and grating coupling, near field excitation.

Module 5 | Nanocomposites 4 hours Nanocomposites as photonic media. Nanocomposite waveguides. Random lasers. Local field enhancement. Multiphase nanocomposites. Nanocomposites for optoelectronics. Polymer dispersed liquid crystals. Nanocomposite metamaterials.

Module 6 Nanostructured Molecular Architectures						4 hours	
Noncovalen	t interactions.	Nanostructured	polymeric	media.	Molecular	machines.	Dendrimers.

4 hours

Sup	Supramolecular structures. Monolayer and multilayer molecular assemblies.									
Mo	dule 7	Spectroscopy and sensing			3 hours					
		cle Spectroscopy, Surface								
Neg	gative In	dex at Optical Frequencies,	The Perfect Lens, Ir	naging and Lithograph	ly					
Mo	Module 8 Contemporary issues: 2 hours									
1/10				Total Lecture						
Tex	xt Book(s)								
1.	Stefan	Alexender Maier, Plasmonic	s – Fundamental an	d Applications, Spring	ger, 2007.					
2.		rasad, Nanophotonics, Wile								
Ref	ference l	Books								
1.	Mark L	. Brongersma and Pieter G.	Kik, Surface Plasm	on Nanophotonics, Sp	ringer, 2007.					
2.		Wehrspohn, Heinz-Siegfrie			otonic Materials:					
		ic Crystals, Plasmonics, and								
3.		w Pelton, Garnett W. Bry		o Metal-Nanoparticle	e Plasmonics, A					
		Science Wise Co–Publicatio	n, 2013							
		ects (Indicative)								
		eposition of plasmonic nanor								
		nemical investigation of hot	•							
		ic simulations with light bear								
		spin Hall effect from single								
5. Fabrication and optical characterisation of metallic nanocubes										
	6. Localized surface plasmon resonance (LSPR) of Nobel metal nanoparticles									
Mode of Evaluation: Review I, II and III										
Recommended by Board of Studies 13-12-2015										
Ap	proved b	y Academic Council	No. 40	Date	18-03-2016					

Course Code	Course Title	L	T	P	J	С
ECE6031	NANOMAGNETISM- FUNDAMENTALS AND	3	0	0	0	3
	APPLICATIONS					
Pre-requisite	ECE5031- Quantum Physics for Nanostructures					

Course Objectives:

The course is aimed to:

- 1. Make them understand the fundamentals of nanomagnetism and their applications.
- 2. Study the magnetism at macro- and nanoscale and their potential effects.
- 3. Enable students to apply the concepts of magnetic nanomaterials in the field of energy storage, biomedicine and environmental applications.

Expected Course Outcomes:

At the end of course students will be able to:

- 1. Gain in-depth knowledge about the concepts of magnetism at macro and nanoscale.
- 2. Obtain the knowledge about magnetism of localized electrons on the atom.
- 3. Gain the fundamentals about ferromagnetism, antiferromagnetism and other magnetic order.
- 4. Identify and understand the concepts of micro- and nanoscale magnetism
- 5. Apply the concepts to the application of magnetic nanomaterials in the field of magnetic recording, energy storage, biomedicine and environmental applications.

Module 1 | Magnetostatics

Introduction - History - Magnetism and hysteresis, Magnetic dipole moment, Magnetic fields, Maxwell's equations, Magnetostatic energy and forces.

Module 2 | Magnetism of electrons

Orbital and spin moments, Magnetic field effects – Zeeman effect, Theory of electronic magnetism, Magnetism of electrons in solids

Module 3 Magnetism of localized electrons on the atom

The hydrogenic atom and angular momentum, The many-electron atom, Paramagnetism, Ions in solids; crystal-field interactions.

Module 4 Ferromagnetism and Exchange

8 hours

3 hours

8 hours

8 hours

Mean field theory, Exchange interactions, Band magnetism, Collective excitations, Anisotropy, Ferromagnetic phenomena

Module 5Antiferromagnetism and other magnetic order4 hoursMolecular field theory of antiferromagnetism, Ferrimagnets, Frustration, Amorphous magnets,
Spin glasses, Magnetic models4 hours

Module 6Micromagnetism and Nanoscale magnetism7 hours

Micromagnetic energy, Domain theory, Reversal, Pinning and Nucleation, Characteristic length scales, Superparamagnetism, Thin films, Thin-film heterostructures, Wires and needles, Small particles, Bulk nanostructures, Novel methods for synthesis of magnetic nanoparticles, Magnetic interactions: a tool to modify the magnetic properties of materials based on nanoparticles.

Module 7	Application	ns of nanomag	netism				5 hours
Magnetic	storage and	recording, N	lagnetic	resonance	Imaging,	Hyperther	mia, Ferrofluid,
Biosensors.							
Module 8	Contempor	ary issues					2 hours
					To	tal Lecture	: 45 hours
Text Book	(s)						
1. J. M. D	D. Coey, Magi	netism and Mag	gnetic M	laterials, Pea	urson Educ	ation, 2010.	,
2. B. D.	Cullity, C. D.	. Graham, Intr	oduction	to Magnet	ic Material	s, John Wi	ley & Sons, Inc,
2009.							
Reference	Books						
1. R. C.	O'Handley, M	Iodern Magne	tic Mate	rials: Princi	ples and A	Applications	s, John Wiley &
Sons, I	nc, 2000.						
2. C Binn	is, Nanomagn	etism: Fundam	nentals ar	nd Applicati	ons, Elsevi	er, 2014.	
3. David	Jiles, Introduc	ction to Magne	tism and	Magnetic N	Aaterials, C	Chapman an	d Hall, 1991.
Mode of E	valuation: Co	ntinuous Asse	ssment 7	Test –I (CA'	Γ-I), Cont	inuous Ass	essment Test –II
							Final Assessment
Test (FAT)		2 2 0		•			
Recommen	ded by Board	of Studies	13-12	2-2015			

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Course Code	Course Title	L	Т	Р	J	С		
ECE 6034	ENERGY TECHNOLOGIES	3	0	0	0	3		
Pre-requisite ECE6034 - Physics and chemistry of solids								
Course Object	ives:							
	ose the students about various energy sources and the possibility	0	f h	arv	vest	ing		
energy v	vith nanomaterials							
Expected Cour	se Outcomes:							
	urse the students will be able to:							
	and the various renewable energy sources.							
	the knowledge on different energy harvesting methods.							
	and thermodynamics and kinetics of fuel cell process with nanomater							
	and choose suitable nanomaterials and nanostructures for photovolta ish different types and performance of solar collectors.	ICS	•					
-	the knowledge of electrochemical energy storage systems.							
-	and the process and design issues in magnetic energy storage systems.	s						
7. Ondersta	and the process and design issues in magnetic energy storage system.							
Module 1 R	enewable Energy Sources		2	2 h	our	S		
Basics and Typ	es of Renewable energy sources.							
Module 2 En	ergy Harvesting			7 h	our	•0		
	and mechanism – Solar, Thermoelectric, Piezoelectric; Electro	dw						
	rgy harvesting devices and applications. Nanomaterials for energy ha							
Module 3 En	ergy Conversion I	Τ	7	/ h	our	S		
	ion – Types and mechanism; Electrochemical energy conversion, the							
	nology; Fuel Cells - fundamentals, classifications, Operating princip							
	thermodynamics and kinetics of fuel cell process, performance evaluations. Nanomaterials as electrode materials for fuel cells.	llua	.t10	n (of 1	ue		
Module 4 En	ergy Conversion II	Т	7	/ h	our	s		
	Photovoltaic fundamentals, Solar cell technologies, Types – D)ye	S	ens	itiz	zed,		
	Copper indium gallium selenide (CIGS), Hybrid, Organic and Plasme ce and parameter analysis of solar cells. Nanomaterials and Nan							
Module 5 En	ergy Conversion III			7 h	our	•6		
	ystems: Types and performance of solar collectors - Flat Plate, Hot	Air						
	c, Compound Parabolic and Fresnel Solar Concentrators, Thermal							
	Solar Collectors, Current and future scope of solar energy.			5				
Modulo (F	angy stangs I			7 1.		•6		
	ergy storage I				our			
	l energy storage systems: Supercapacitors - Differences betwee and batteries, classifications of supercapacitors. Batteries: Prima			-				
	state and molten solvent batteries; Lead acid batteries; Nickel Cadn	-				-		
	d Aluminum Batteries. Nanostructured and Hybrid materials as							
batteries and ca	•		5.01	24	-5	_ 01		

Mod	ule 7	Energy storage II			6 hours		
storag	ge mat	nergy storage systems (SM erials – Types, thermo ph lications. Heat transfer fluid	ysical properties, P	hase change materials			
Module 8 Contemporary issues:							
Adva	inced T	Copics					
				Total Lectur	re: 45 hours		
	Book(
		Singh Solanki, Solar Photo earning Private limited, 201		entals, Technologies and	d Applications,		
		liu, Leizhang, Xueliang sun sion, Wiley publications, 20		chnologies for energy st	torage and		
	rence]						
	•	1. Drapcho, Nghiem Phu N ompanies, 2008	huan and Terry H. W	Valker, Biofuels Engine	ering, McGraw-		
	Viswar Press ,2	nathan, B and M Aulice Sci 2006	bioh, Fuel Cells – Pr	inciples and Applicatio	ns, Universities		
3. \$	Schaef	fer, John, Real Goods Solar Technologies and Sustaina			o Renewable		
4. I	Frank I	Kreith and D.Yogi Goswam ress, 2007	<u> </u>		ewable Energy,		
5. J	John T	widell and Tony Weir, Ren	ewable Energy Reso	urces, Taylor & Francis	s, USA, 2006		
Mode (CAT	e of Ev	aluation: Continuous Asses eminar / Challenging Assig	sment Test –I (CAT	-I), Continuous Assess	ment Test –II		
		ded by Board of Studies	13-12-2015				
		y Academic Council	No. 40				

Course Code	Course Title	LTPJC
ECE6035	SPINTRONICS	$\frac{2}{2}$ 0 0 4 3
Pre-requisite	ECE5031- Quantum Physics for Nanostructures	
Course Object	ives :	
The course aime	ed to:	
1. Mał	te them understand the spin based electronics.	
	ly the magnetic materials, Spintronic based devices and fabrication.	
Expected Cou		
The student will		
	the knowledge about Paramagnetism & diamagnetism.	
	aire the understanding and importance of Micromagnetics.	
	in the fundamental knowledge of Magnetic Materials	
	erstand the Electron Transport in Magnetic Systems	1 1
	y properties of magnetic materials using advanced characterization to	ools and
	niques. in the design and scope of Spintronic Device fabrication Techniques	
	ramagnetism & diamagnetism	2 hours
	dered state, Itinerant-electron magnetism, Localized Magnetic Syster	
Wagnetically of	dered state, filleralit electron magnetism, Elecanzed magnetic 57ster	
Module 2 Mi	cromagnetics	3 hours
	ingle domain systems, Domain Walls, Exchange Bias and Magnetic A	
8		1.
Module 3 Ma	agnetic Materials	3 hours
High-density re	cording materials, Soft Magnetic Materials (Ferrites), Magnetic Thin	Films, Dilute
Magnetic semi	conductors, Hemsler Alloys, SQUID Magnetometer, Highly S	pin Polarized
Systems, Molec	ule-based magnets, Single-molecule magnets.	
	ectron Transport in Magnetic Systems	5 hours
0	Spin Polarization, Idea of Tunneling, Magnetoresistance,	Anisotropic
Magnetoresista	nce (AMR), Hall Effect (Planar & Anomalous) and Spin Polarized sta	tes.
		I
	aracterization of Magnetic Materials	6 hours
• •	SQUID, VSM, Torque, Faraday Balance, Kerr Effect, Ma	gnetic Force
Microscopy, Sp	in Polarized STM.	
1	intronic Devices	6 hours
-	rigins of Spin, Spin Mechanics, Origins of Spintronics, Spin	
0	nce, Giant Magnetoresistance (GMR), Colossal Magnetoresistance, Tunneling Magnetoresistance. Two-terminal devices-Spin valv	
0	agnetic Field sensors, Read- Heads, MRAMS, Three-terminal Devic	
Spin SET, and S	-	es- spin ren,
Spin SET, and s	phil LLD.	
Module 7 Sp	intronic Device fabrication Techniques	3 hours
1	ce fabrication methods-Growth of multilayer Structures, Lithograp	
Assembly.	te menteurion methods crown of making of Structures, Enhoging	ing and ben
Module 8 Co	ntemporary issues:	2 hours

				Total Lectur	re 30 hours
Text Book(s)					
1		akakima, and Inomata, Giant Ma	agneto-Resistive I	Devices Springer V	Verlag 2002
2		halom, D. Loss, and N.Samarth,			
2		tion, Nano Science Technology			intuill
Ref	erence Bo		series, opringer, 2		
1					
2	2 D.L. Mills, J. A.C. Brand Nanomagnetism, Elsevier Science and Technology, 2006.				
3					
4					
5					
6					
7	U. N.Ha	rtmann, Magnetic Multi-layers	and Giant Mag	netoresistance: Fu	ndamentals and
	Industria	l Applications, Springer, 2000.			
8					r, 2001.
Mo	de of Eval	uation: Continuous Assessment	Test –I (CAT-I),	Continuous Assess	sment Test –II
(CA	T-II), Ser	ninar / Challenging Assignments	s / Completion of I	MOOC / QUIZ, Fi	nal Assessment
Tes	t (FAT).				
Тур	oical Proj	ects			
1. 1	1. Fabrication of magnetic tunnel junctions (MTJ) with MgO or AlO insulating barriers				
2. Spin pumping and high frequency spin dynamics in MTJs					
3. MTJ sensors for biological applications					
4. Theory of spin-polarized transport and pure spin currents					
5. Topological insulator-based spintronic devices.					
Mode of Evaluation: Review I, II and III					
Rec	ommende	d by Board of Studies	13-12-2015		
App	proved by	Academic Council	No. 40	Date	18-03-2016

Course Code	Course Title	L T P J C
ECE6039	NANOELECTRONIC CIRCUIT DESIGN	3 0 0 0 3
Pre-requisite	ECE6032 - Nanoelectronics	

Course Objectives:

- To introduce students to the emerging design paradigms in various new nanotechnologies, for device and circuits.
- To bridge the existing gap between nanoelectronic device research and nanosystems design.

Expected Course Outcomes:

The student will be able to

- 1. Obtain the knowledge on advanced Nanoscale devices
- 2. Understand the operation and design FinFET based circuits.
- 3. Design reliable circuits using nanowire arrays and CNT interconnects.
- 4. Design logic circuits using quantum cellular automata.
- 5. Understand the design aspects of application specific Nanoscale ICs.
- 6. Model the circuits of Fin-FETs, CNT-FETs, GNR-FETs, RTDs and quantum dot devices using various SPICE versions.

Module 1 Introduction to advanced nanoelectronic devices

New device structures for next generation nanotechnology - carbon nanotube field-effect transistors (CNFETs), FinFETs, nanowire FETs, III/V compound-based devices, graphene nanoribbon devices, resonant tunneling diodes and quantum dot devices.

Module 2 | FinFET circuit and SRAM design

8 hours Shorted-Gate and Independent-Gate FinFETs, Logic Design Using SG/IG-Mode FinFETs, Principle of TCMS, Logic Design Using TCMS, Latch Design Using SG/IG-Mode FinFETs, Precharge-Evaluate Logic Circuits, FinFET SRAM Design: Physics, Theory, and Modeling of FinFET Devices for SRAM Applications; Low-Power, High-Performance 90-nm DG-FinFET SRAM Design.

Module 3	Reliable Circuits Design with Nanowire Arrays and CNT	
	Interconnects	

Nanowire Fabrication Techniques, Crossbar Technologies, Architecture of Nanowire Crossbars, Decoder Logic Design. Emerging interconnect technologies: Study of Performances of Low-k Cu, CNTs, and Optical Interconnects; Local Interconnects: CNT Bundles Versus Cu and Global and Semi-global Interconnects.

Module 4 | Circuit Design with Quantum Cellular Automata

7 hours

2 hours

QCA Fundamentals, Basic Logic Gates and Interconnect, Logic Design with QCA and Fabrication Technology and Challenges.

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ASIC Building Blocks: Nanowires and XnwFE1s, NASIC Circuit Styles, NASIC Logic St	NASIC Building Blocks: Nanowires and xnwFETs, NASIC Circuit Styles, NASIC Logic Styles,		
NASIC Architectures and manufacturing methods.			

Module 6	Circuit Design with Carbon Nanotube FETs & Resonant	8 hours
	Tunneling Diodes	

Mis-Positioned and Immune CNT Logic Design, Metallic-CNT-Immune CNFET				
Circuits.Metallic-CNT-Immune CNFET	Circuits. Bistable L	logic Using RTDs,	Noise Margins of	
RTD-HBT Threshold Logic Gates, Mon	ostable–Bistable L	ogic Elements and	Circuit Examples	
for RTD-Based Devices.				
Module 7 Circuit design with Graphe			5 hours	
Recent developments in Graphene Transis	stors, Analog Circu	its, Digital Circuits:	GNRFET Digital	
Circuits, Ambipolar Logic Circuits.				
Module 8 Contemporary issues:			2 hours	
Advanced Topics				
		Total Lectu	re: 45 hours	
Text Book(s)				
1. Niraj K. Jha and Deming Chen, Nanc	electronic Circuit I	Design, Springer pul	blications, 2011.	
2. K. Goser, P. Glosekotter, Nanoelectro	onics and Nanosyst	ems, Springer, 2015	5.	
Reference Books				
1. Yuan Taur and TakNing, Fundame	ntals of Modern V	LSI Devices, Cam	bridge University	
Press, Newyark, 1998.				
3. Karl Goser, Peter Glosekotter, Jan	. Karl Goser, Peter Glosekotter, Jan Dienstuhl, Nanoelectronics and Nanosystems- From			
Transistors to Molecular and Quantum	Transistors to Molecular and Quantum Devices, Springer-Verlag, 2004.			
4. John P. Uyemura, Introduction to VL	4. John P. Uyemura, Introduction to VLSI Circuits and Systems, John Wiley & Sons, Inc, 2002.			
Mode of Evaluation: Continuous Assessment Test -I (CAT-I), Continuous Assessment Test -II				
(CAT-II), Seminar / Challenging Assignments / Completion of MOOC / QUIZ, Final Assessment				
Test (FAT).				
Recommended by Board of Studies 13-12-2015				
Approved by Academic CouncilNo. 40Date18-03-2016				